VN820

High-side driver

Features

Type	$R_{DS(on)}$	I_{OUT}	V_{CC}
VN820 VN820SP VN820-B5 VN820SO VN820PT	40 mΩ	9 A	36 V
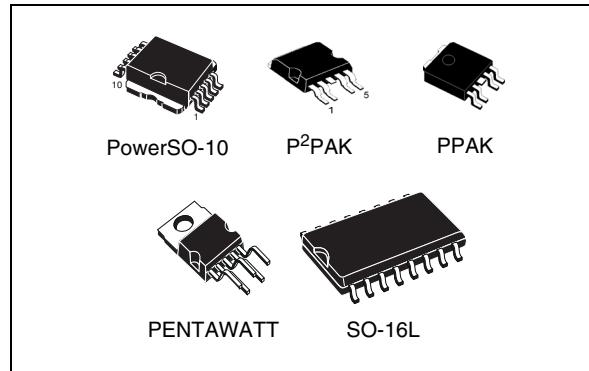
- CMOS compatible input
- On-state open load detection
- Off-state open load detection
- Shorted load protection
- Under-voltage and over-voltage shutdown
- Protection against loss of ground
- Very low standby current
- Reverse battery protection (see *Application schematic*)

PowerSO-10   P²PAK   PPAK

PENTAWATT   SO-16L

Description

The VN820 is a monolithic device designed in STMicroelectronic's VIPower M0-3 technology. The VN820 is intended for driving any type of load with one side connected to ground. The active V_{CC} pin voltage clamp protects the device against low energy spikes (see ISO7637 transient compatibility table).

Active current limitation combined with thermal shutdown and automatic restart protects the device against over-load. The device detects the open load condition in both the on and off-state. In the off-state the device detects if the output is shorted to V_{CC}. The device automatically turns off in the case where the ground pin becomes disconnected.

Table 1.   Device summary

Package	Order codes	
	Tube	**Tape and reel**
PENTAWATT	VN820	-
PowerSO-10	VN820SP	VN820SP13TR
P²PAK	VN820-B5	VN820-B513TR
PPAK	VN820PT	VN820PT13TR
SO-16L	VN820SO	VN820SO13TR

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Figure 1.   Block diagram

Figure 2.   Configuration diagram (top view)
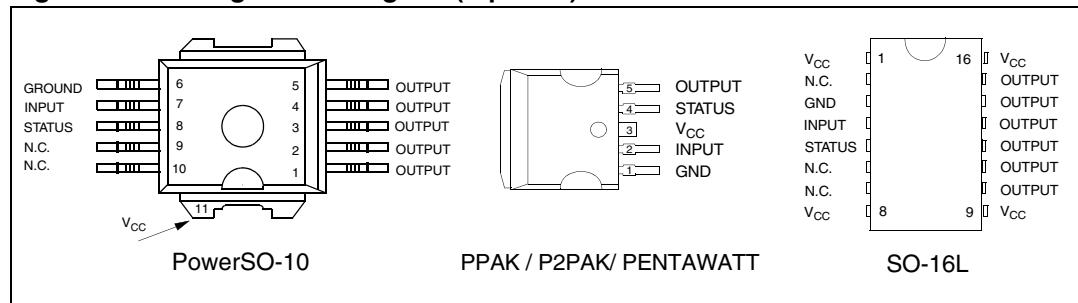
Table 2.   Suggested connections for unused and not connected pins

Connection / pin	Status	N.C.	Output	Input
Floating	X	X	X	X
To ground		X		Through 10KΩ resistor

2 Electrical specifications

Figure 3. Current and voltage conventions
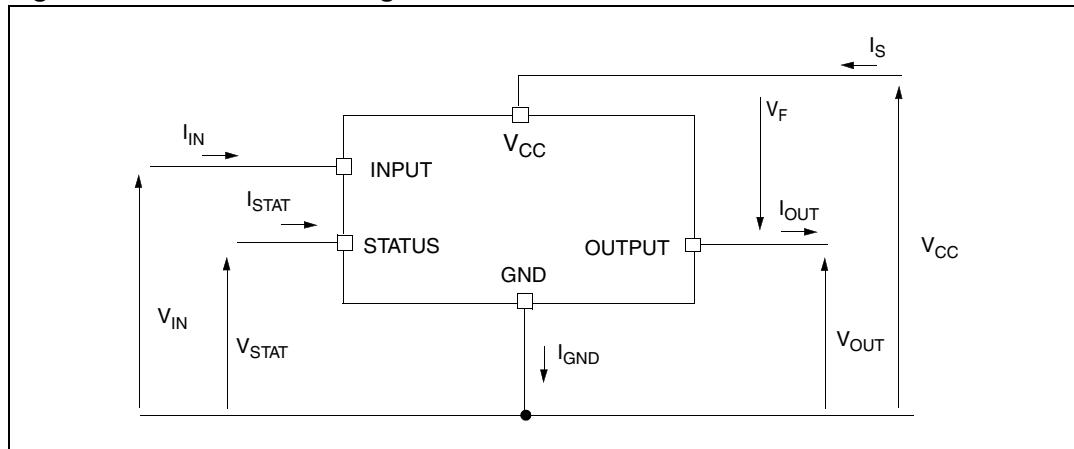
2.1 Absolute maximum ratings

Stressing the device above the rating listed in the "Absolute maximum ratings" table may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the operating sections of this specification is not implied. Exposure to Absolute maximum rating conditions for extended periods may affect device reliability. Refer also to the STMicroelectronics sure program and other relevant quality document.

Table 3. Absolute maximum ratings

Symbol	Parameter	Value					Unit
		SO-16L	**PowerSO-10**	**PENTAWATT**	**P²PAK**	**PPAK**	
V_{CC}	DC supply voltage	41					V
- V_{CC}	Reverse DC supply voltage	- 0.3					V
- I_{gnd}	DC reverse ground pin current	- 200					mA
I_{OUT}	DC output current	Internally limited					A
- I_{OUT}	Reverse DC output current	- 9					A
I_{IN}	DC input current	+/- 10					mA
I_{STAT}	DC Status current	+/- 10					mA
V_{ESD}	Electrostatic discharge (human body model: R = 1.5KΩ; C = 100pF) - INPUT - STATUS - OUTPUT - V_{CC}	4000 4000 5000 5000					V V V V

Table 3. Absolute maximum ratings (continued)

Symbol	Parameter	Value					Unit
		SO-16L	PowerSO-10	PENTAWATT	P^{2}PAK	PPAK	
E_{MAX}	Maximum switching energy (L = 4mH; R_L = 0Ω; V_{bat} = 13.5V; T_{jstart} = 150ºC; I_L = 13A)		481		481		mJ
E_{MAX}	Maximum switching energy (L = 3.7mH; R_L = 0Ω; V_{bat} = 13.5V; T_{jstart} = 150ºC; I_L = 13A)	438					mJ
E_{MAX}	Maximum switching energy (L = 4.48mH; R_L = 0Ω; V_{bat} = 13.5V; T_{jstart} = 150ºC; I_L = 13A)					526	mJ
P_{tot}	Power dissipation T_C = 25°C	8.3	65.8	65.8	65.8	65.8	W
T_j	Junction operating temperature	Internally limited					°C
T_c	Case operating temperature	- 40 to 150					°C
T_{stg}	Storage temperature	- 55 to 150					°C

2.2 Thermal data

Table 4. Thermal data

Symbol	Parameter	Max. value					Unit
		SO-16L	PowerSO-10	PENTAWATT	P^{2}PAK	PPAK	
$R_{thj-case}$	Thermalresistance junction-case	-	1.9	1.9	1.9	1.9	°C/W
$R_{thj-lead}$	Thermalresistance junction-lead	15	-	-	-	-	°C/W
$R_{thj-amb}$	Thermalresistance junction-ambient	65[1]	51.9[2]	61.9[2]	51.9[2]	76.9[2]	°C/W
		48[3]	37[4]	-	37[4]	45[4]	°C/W

1. When mounted on FR4 printed circuit board with 0.5cm^2 of Cu (at least 35μm thick) connected to all V_{CC} pins.

2. When mounted on a standard single-sided FR-4 board with 0.5cm^2 of Cu (at least 35μm thick).

3. When mounted on FR4 printed circuit board with 6cm^2 of Cu (at least 35μm thick) connected to all V_{CC} pins.

4. When mounted on a standard single-sided FR-4 board with 6cm^2 of Cu (at least 35μm thick).

2.3 Electrical characteristics

Values specified in this section are for 8V < V_{CC} < 36V; -40°C < T_j < 150°C, unless otherwise stated.

Table 5.   Power

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
V_{CC}	Operating supply voltage		5.5	13	36	V
V_{USD}	Under-voltage shutdown		3	4	5.5	V
$V_{USDhyst}$	Under-voltage shutdown hysteresis			0.5		V
V_{OV}	Over-voltage shutdown		36			V
R_{ON}	On-state resistance	I_{OUT} = 3A; T_j = 25°C; V_{CC} > 8V I_{OUT} = 3A; V_{CC} > 8V			40 80	mΩ mΩ
I_S	Supply current	Off-state; V_{CC} = 13V; V_{IN} = V_{OUT} = 0V Off-state; V_{CC} = 13V; V_{IN} = V_{OUT} = 0V; T_j = 25°C On-state; V_{CC} = 13V; V_{IN} = 5V; I_{OUT} = 0A		10 10 2	25 20 3.5	µA µA mA
$I_{L(off1)}$	Off-state output current	V_{IN} = V_{OUT} = 0V	0		50	µA
$I_{L(off2)}$	Off-state output current	V_{IN} = 0V; V_{OUT} = 3.5V	-75		0	µA
$I_{L(off3)}$	Off-state output current	V_{IN} = V_{OUT} = 0V; V_{CC} = 13V; T_j = 125°C			5	µA
$I_{L(off4)}$	Off-state output current	V_{IN} = V_{OUT} = 0V; V_{CC} = 13V; T_j = 25°C			3	µA

Table 6.   Switching (V_{CC}=13V)

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$t_{d(on)}$	Turn-on delay time	R_L = 4.3Ω from V_{IN} rising edge to V_{OUT} = 1.3V		30		µs
$t_{d(off)}$	Turn-off delay time	R_L = 4.3Ω from V_{IN} falling edge to V_{OUT} = 11.7V		30		µs
$dV_{OUT}/dt_{(on)}$	Turn-on voltage slope	R_L = 4.3Ω from V_{OUT} = 1.3V to V_{OUT}=10.4V	See *Figure 21.*			V/µs
$dV_{OUT}/dt_{(off)}$	Turn-off voltage slope	R_L = 4.3Ω from V_{OUT} = 11.7V to V_{OUT} = 1.3V	See *Figure 22.*			V/µs

Table 7.   **Input pin**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
V_{IL}	Input low level				1.25	V
I_{IL}	Low level input current	$V_{IN} = 1.25V$	1			μA
V_{IH}	Input high level		3.25			V
I_{IH}	High level input current	$V_{IN} = 3.25V$			10	μA
V_{hyst}	Input hysteresis voltage		0.5			V
V_{ICL}	Input clamp voltage	$I_{IN} = 1mA$ $I_{IN} = -1mA$	6	6.8 - 0.7	8	V V

Table 8.   **V_{CC} output diode**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
V_F	Forward on voltage	- $I_{OUT} = 2A$; $T_j = 150°C$			0.6	V

Table 9.   **Status pin**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
V_{STAT}	Status low output voltage	$I_{STAT} = 1.6mA$			0.5	V
I_{LSTAT}	Status leakage current	Normal operation; $V_{STAT} = 5V$			10	μA
C_{STAT}	Status pin input capacitance	Normal operation; $V_{STAT} = 5V$			100	pF
V_{SCL}	Status clamp voltage	$I_{STAT} = 1mA$ $I_{STAT} = - 1mA$	6	6.8 - 0.7	8	V V

Table 10.   **Protections[1]**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
T_{TSD}	Shutdown temperature		150	175	200	°C
T_R	Reset temperature		135			°C
T_{hyst}	Thermal hysteresis		7	15		°C
t_{SDL}	Status delay in over-load condition	$T_j > T_{jsh}$			20	ms
I_{lim}	Current limitation	$9V < V_{CC} < 36V$ $5.5V < V_{CC} < 36V$	9	13	20 20	A A
V_{demag}	Turn-off output clamp voltage	$I_{OUT} = 3 A$; $V_{IN} = 0V$; $L = 6mH$	V_{CC} - 41	V_{CC} - 48	V_{CC} - 55	V

1. To ensure long term reliability under heavy over-load or short circuit conditions, protection and related diagnostic signals must be used together with a proper software strategy. If the device operates under abnormal conditions this software must limit the duration and number of activation cycles.

Table 11.   Open load detection

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
I_{OL}	Open load on-state detection threshold	V_{IN} = 5V	70	150	300	mA
$t_{DOL(on)}$	Open load on-state detection delay	I_{OUT} = 0A			200	µs
V_{OL}	Open load off-state voltage detection threshold	V_{IN} = 0V	1.5	2.5	3.5	V
$t_{DOL(off)}$	Open load detection delay at turn-off				1000	µs
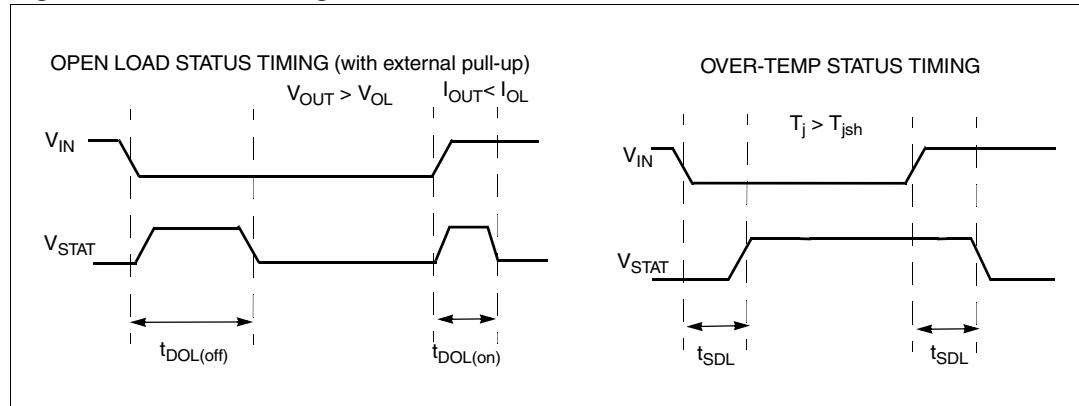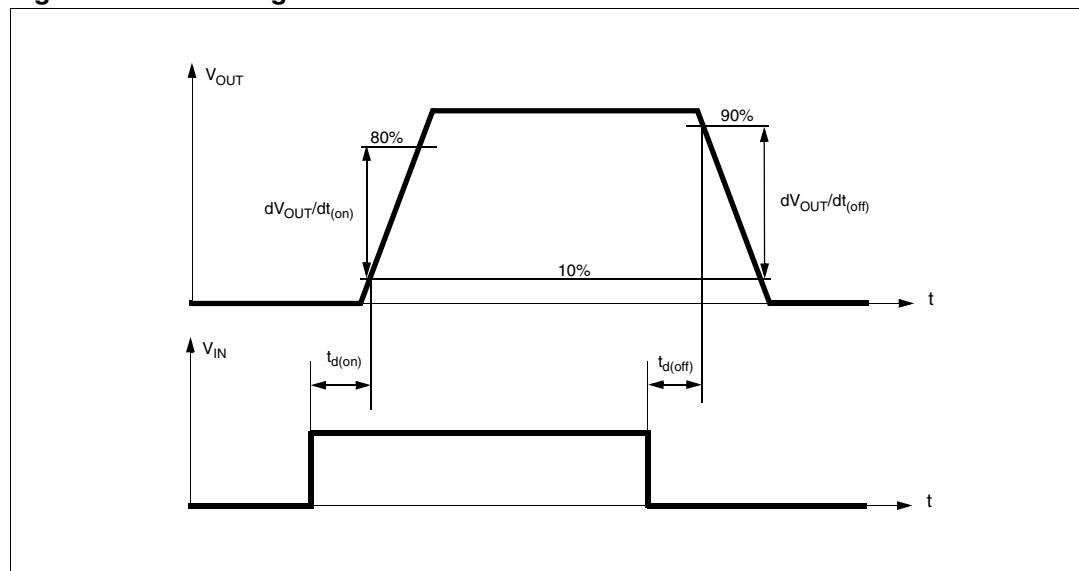
Figure 4.   Status timings

Figure 5.   Switching time waveforms

Table 12.   Truth table

Conditions	Input	Output	Status
Normal operation	L H	L H	H H
Current limitation	L H H	L X X	H $(T_j < T_{TSD})$ H $(T_j > T_{TSD})$ L
Over-temperature	L H	L L	H L
Under-voltage	L H	L L	X X
Over-voltage	L H	L L	H H
Output voltage > V_{OL}	L H	H H	L H
Output current < I_{OL}	L H	L H	H L

Table 13.   Electrical transient requirements

ISO T/R 7637/1 Test pulse	Test level				
	I	**II**	**III**	**IV**	**Delays and impedance**
1	- 25V[1]	- 50V[1]	- 75V[1]	- 100V[1]	2ms, 10Ω
2	+ 25V[1]	+ 50V[1]	+ 75V[1]	+ 100V[1]	0.2ms, 10Ω
3a	- 25V[1]	- 50V[1]	- 100V[1]	- 150V[1]	0.1μs, 50Ω
3b	+ 25V[1]	+ 50V[1]	+ 75V[1]	+ 100V[1]	0.1μs, 50Ω
4	- 4V[1]	- 5V[1]	- 6V[1]	- 7V[1]	100ms, 0.01Ω
5	+ 26.5V[1]	+ 46.5V[2]	+ 66.5V[2]	+ 86.5V[2]	400ms, 2Ω

1. All functions of the device are performed as designed after exposure to disturbance.

2. One or more functions of the device is not performed as designed after exposure and cannot be returned to proper operation without replacing the device.

Figure 6.   Waveforms
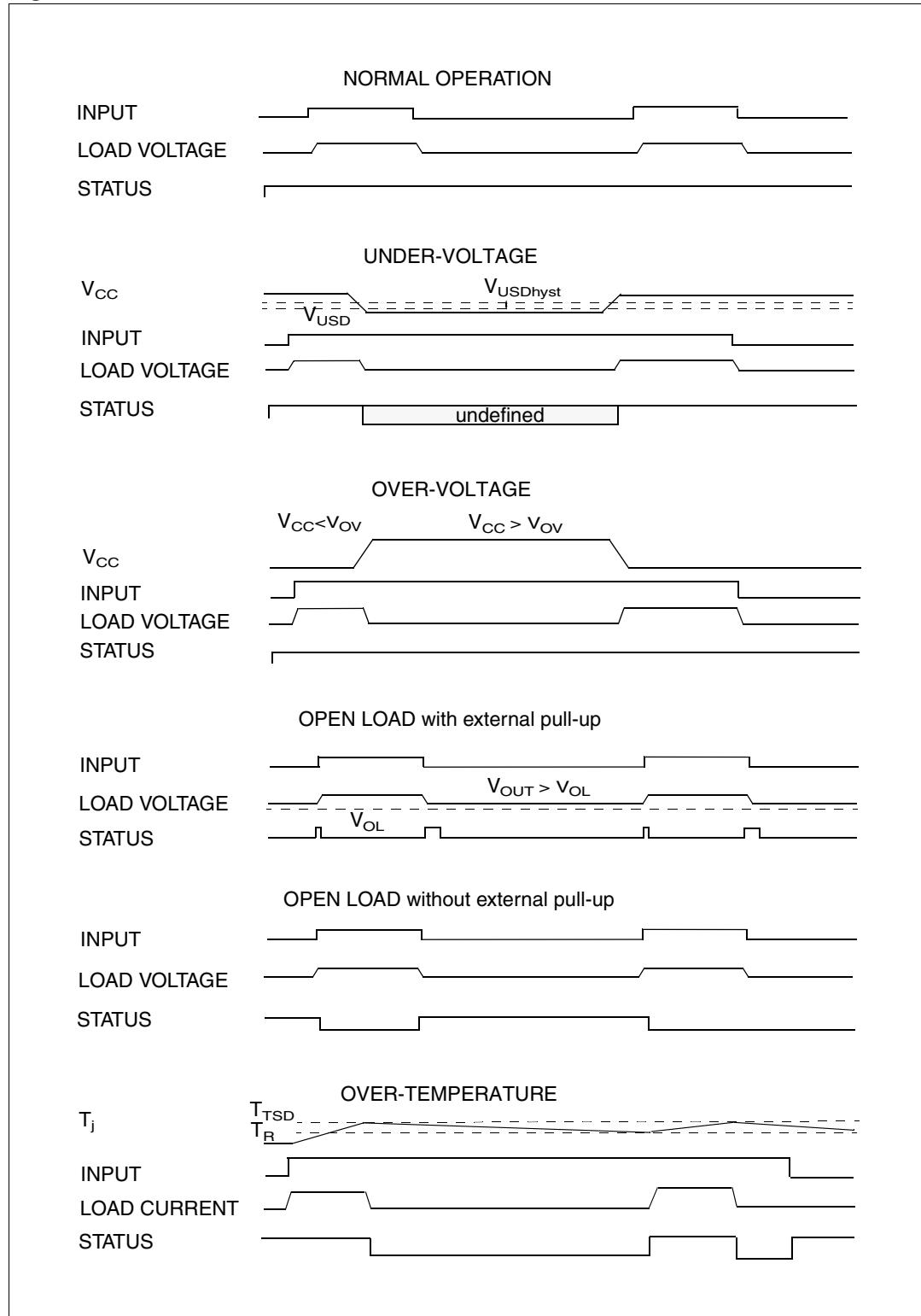
2.4 Electrical characteristics curves

Figure 7. Off-state output current
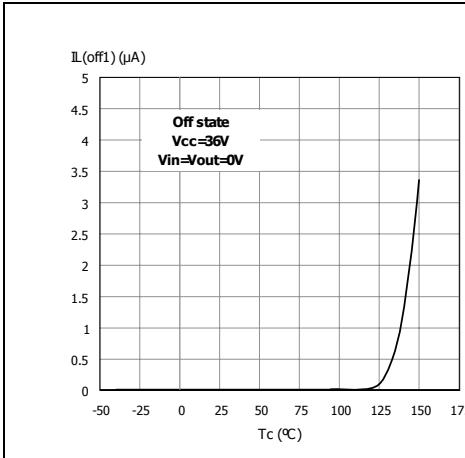
Figure 8. High level input current
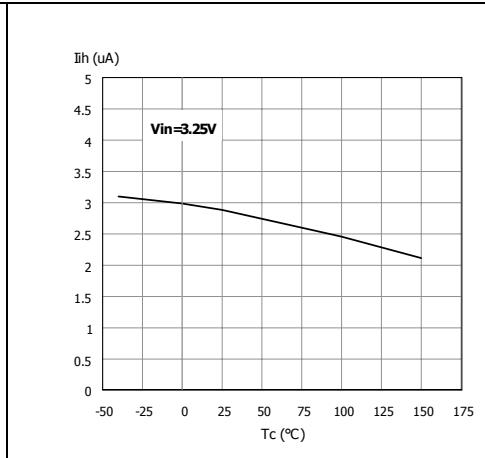
Figure 9. Input clamp voltage
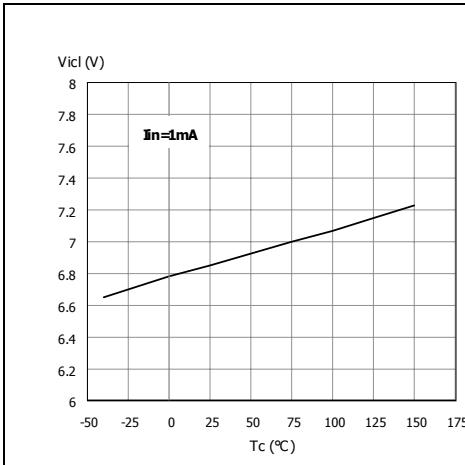
Figure 10. Status leakage current
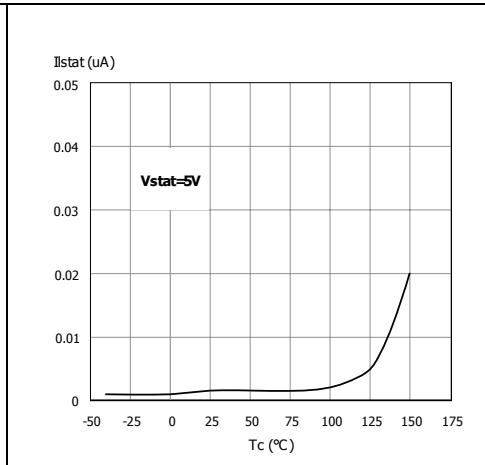
Figure 11. Status low output voltage
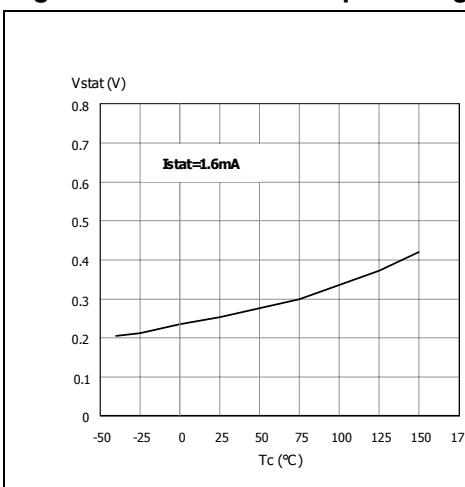
Figure 12. Status clamp voltage
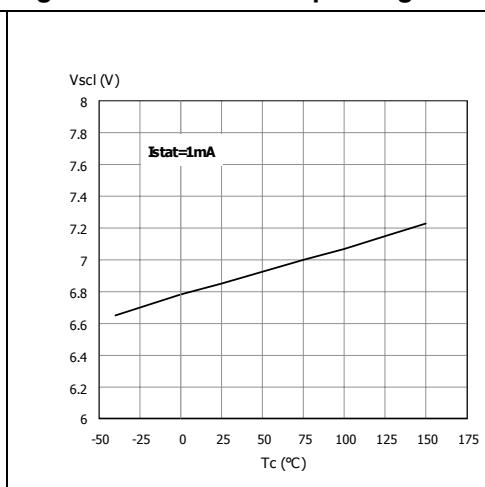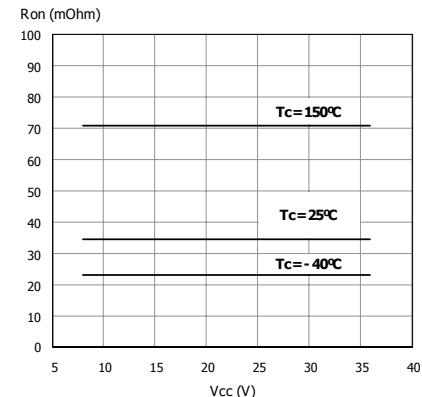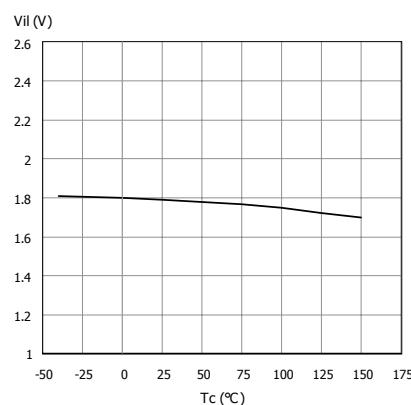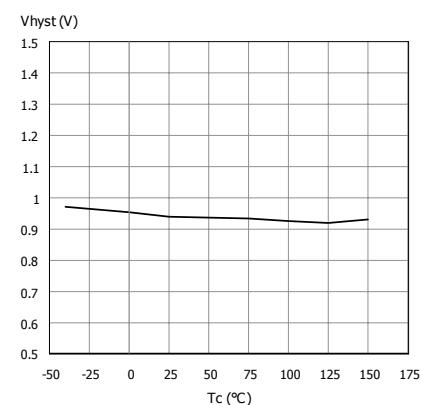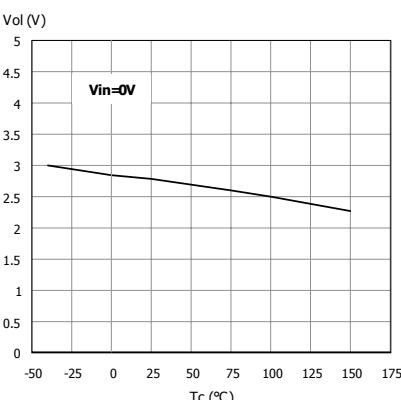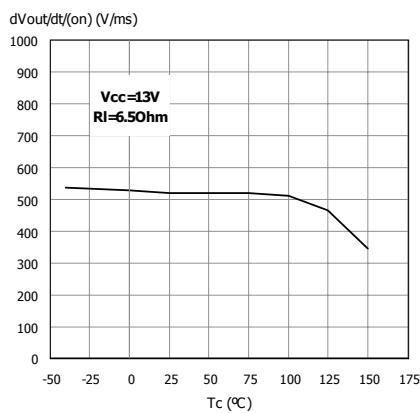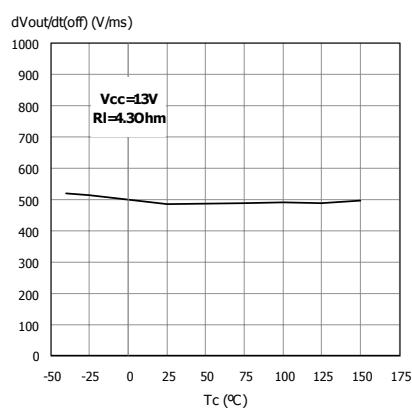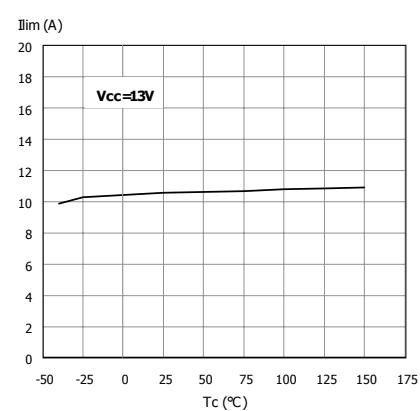
Figure 13.   On-state resistance Vs T$_{case}$ **Figure 14.   On-state resistance Vs V$_{CC}$**
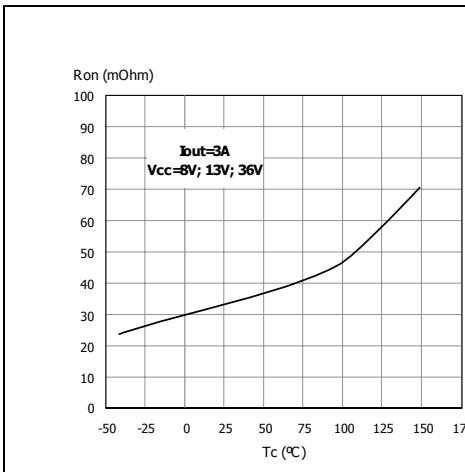
Figure 15.   Open load on-state detection threshold   **Figure 16.   Input high level**
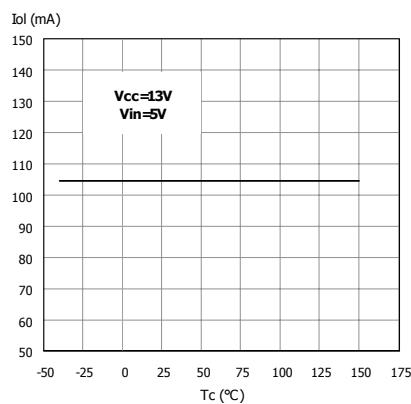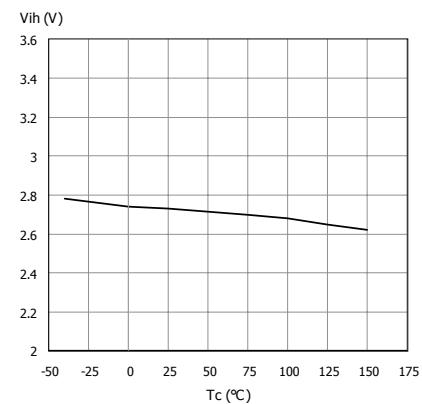
Figure 17.   Input low level   **Figure 18.   Input hysteresis voltage**

Figure 19.   Over-voltage shutdown
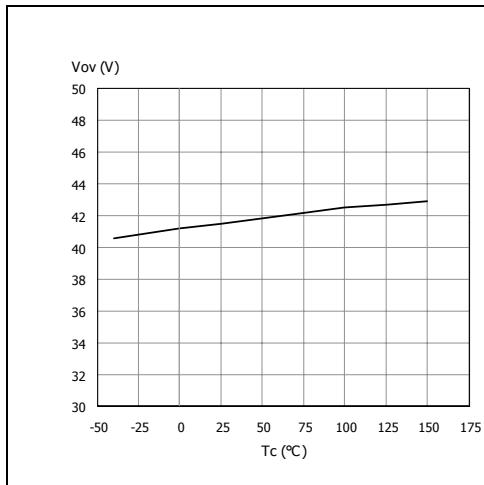
Figure 20.   Open load off-state voltage detection threshold

Figure 21.   Turn-on voltage slope

Figure 22.   Turn-off voltage slope

Figure 23. I_{lim} Vs T_{case}

3 Application information

Figure 24. Application schematic
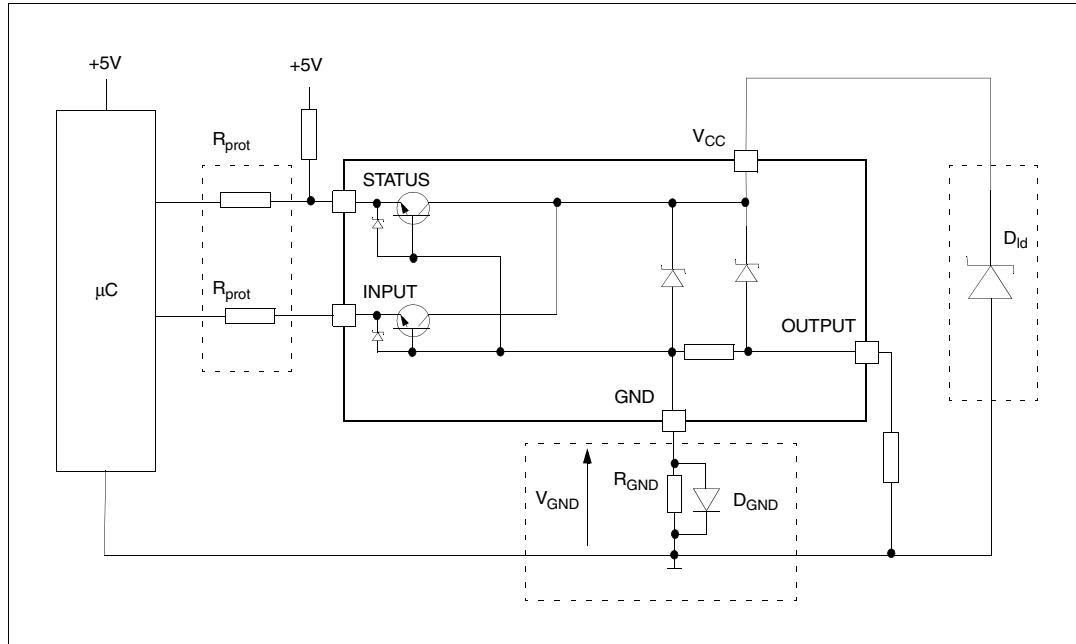
3.1 GND protection network against reverse battery

3.1.1 Solution 1: resistor in the ground line (R_{GND} only)

This can be used with any type of load.

The following is an indication on how to dimension the R_{GND} resistor.

1. $R_{GND} \leq 600mV / (I_{S(on)max})$.
2. $R_{GND} \geq (- V_{CC}) / (- I_{GND})$

where $- I_{GND}$ is the DC reverse ground pin current and can be found in the absolute maximum rating section of the device datasheet.

Power Dissipation in R_{GND} (when $V_{CC} < 0$: during reverse battery situations) is:

$$P_D = (- V_{CC})^2 / R_{GND}$$

This resistor can be shared amongst several different HSDs. Please note that the value of this resistor should be calculated with formula (1) where $I_{S(on)max}$ becomes the sum of the maximum on-state currents of the different devices.

Please note that if the microprocessor ground is not shared by the device ground then the R_{GND} will produce a shift ($I_{S(on)max} * R_{GND}$) in the input thresholds and the status output values. This shift will vary depending on how many devices are ON in the case of several high-side drivers sharing the same R_{GND}.

If the calculated power dissipation leads to a large resistor or several devices have to share the same resistor then ST suggests to utilize Solution 2 (see below).

3.1.2 Solution 2: diode (D$_{GND}$) in the ground line

A resistor (R$_{GND}$ = 1kΩ) should be inserted in parallel to D$_{GND}$ if the device drives an inductive load.

This small signal diode can be safely shared amongst several different HSDs. Also in this case, the presence of the ground network will produce a shift (≈ 600mV) in the input threshold and in the status output values if the microprocessor ground is not common to the device ground. This shift will not vary if more than one HSD shares the same diode/resistor network.

Series resistor in INPUT and STATUS lines are also required to prevent that, during battery voltage transient, the current exceeds the absolute maximum rating.

Safest configuration for unused INPUT and STATUS pin is to leave them unconnected.

3.2 Load dump protection

D$_{ld}$ is necessary (Voltage Transient Suppressor) if the load dump peak voltage exceeds the V$_{CC}$ max DC rating. The same applies if the device is subject to transients on the V$_{CC}$ line that are greater than the ones shown in the ISO 7637-2: 2004(E) table.

3.3 MCU I/Os protection

If a ground protection network is used and negative transient are present on the V$_{CC}$ line, the control pins will be pulled negative. ST suggests to insert a resistor (R$_{prot}$) in line to prevent the μC I/Os pins to latch-up.

The value of these resistors is a compromise between the leakage current of μC and the current required by the HSD I/Os (Input levels compatibility) with the latch-up limit of μC I/Os.

$-V_{CCpeak}/I_{latchup} \leq R_{prot} \leq (V_{OH\mu C}-V_{IH}-V_{GND}) / I_{IHmax}$

Calculation example:

For V$_{CCpeak}$= - 100V and I$_{latchup}$ ≥ 20mA; V$_{OH\mu C}$ ≥ 4.5V

$5k\Omega \leq R_{prot} \leq 65k\Omega$

Recommended values: R$_{prot}$ =10kΩ.

3.4 Open load detection in off-state

Off-state open load detection requires an external pull-up resistor (R$_{PU}$) connected between OUTPUT pin and a positive supply voltage (V$_{PU}$) like the +5V line used to supply the microprocessor.

The external resistor has to be selected according to the following requirements:

1. no false open load indication when load is connected: in this case we have to avoid V$_{OUT}$ to be higher than V$_{Olmin}$; this results in the following condition V$_{OUT}$= (V$_{PU}$ / (R$_L$+R$_{PU}$)) R$_L$ < V$_{Olmin}$.
2. no misdetection when load is disconnected: in this case the V$_{OUT}$ has to be higher than V$_{OLmax}$; this results in the following condition R$_{PU}$ < (V$_{PU}$ − V$_{OLmax}$) / I$_{L(off2)}$.

Because $I_{s(OFF)}$ may significantly increase if V_{out} is pulled high (up to several mA), the pull-up resistor R_{PU} should be connected to a supply that is switched off when the module is in standby.

The values of V_{OLmin}, V_{OLmax} and $I_{L(off2)}$ are available in the electrical characteristics section.

Figure 25. Open load detection in off-state
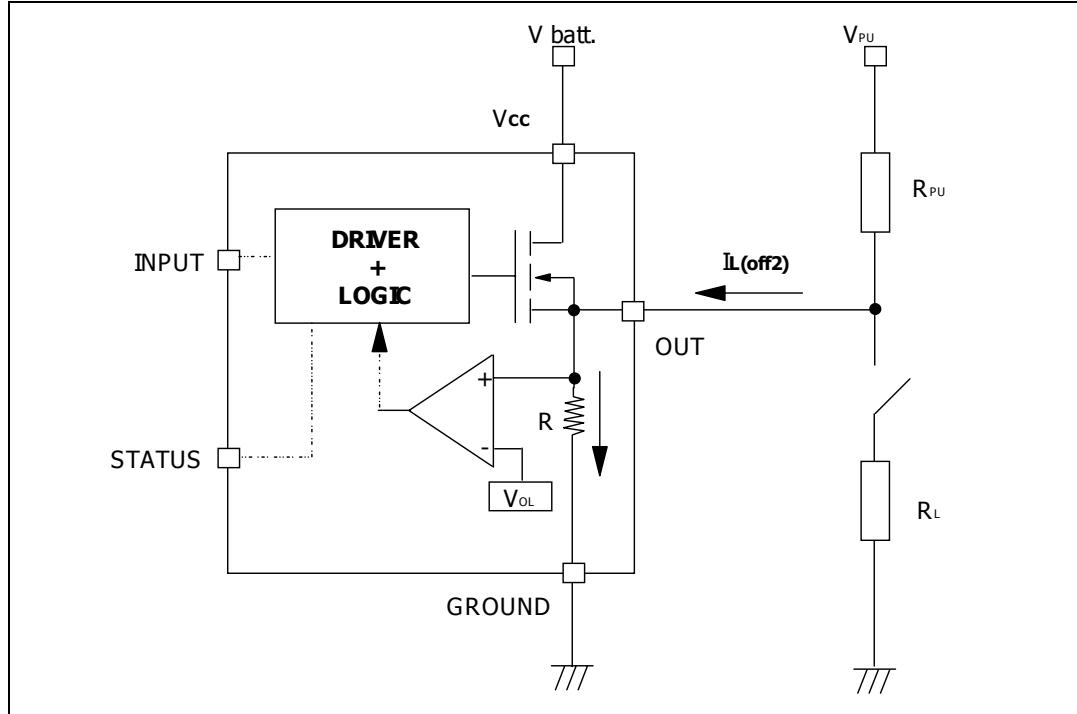
3.5 PowerSO-10, P²PAK, PENTAWATT maximum demagnetization energy (V_{CC} = 13.5V)

Figure 26.   PowerSO-10, P²PAK, PENTAWATT maximum turn-off current versus inductance
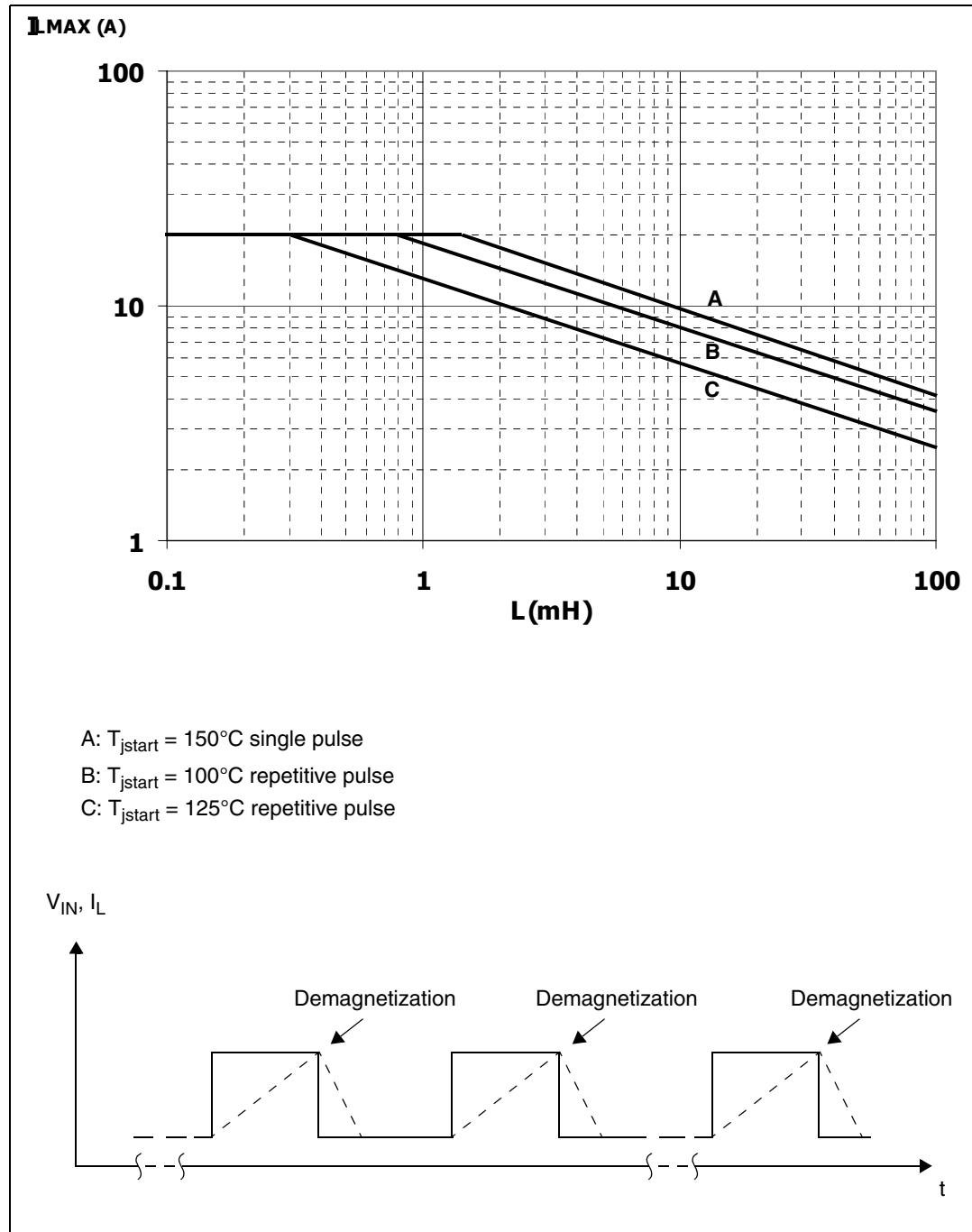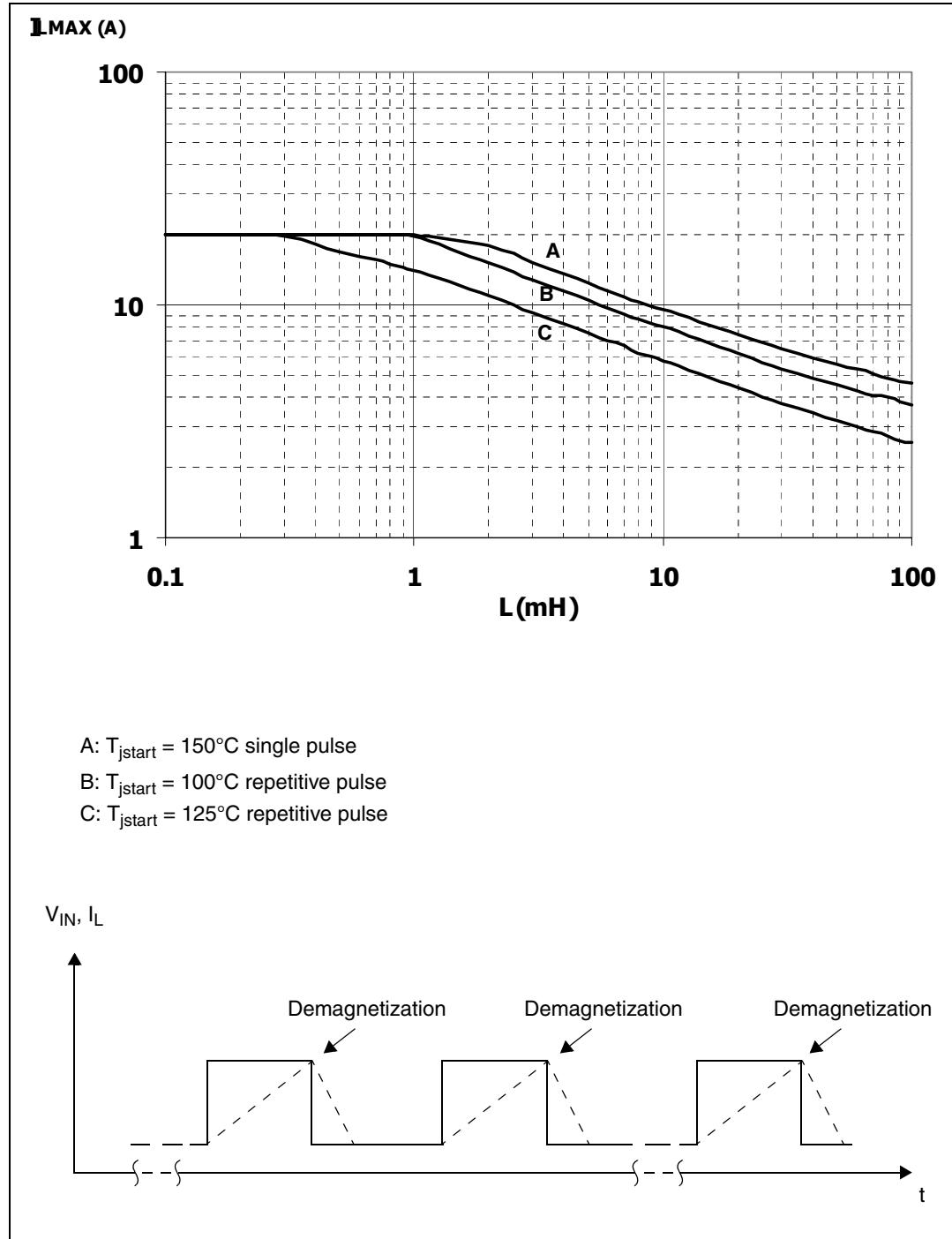
A: T_{jstart} = 150°C single pulse

B: T_{jstart} = 100°C repetitive pulse

C: T_{jstart} = 125°C repetitive pulse

Note: *Values are generated with R_L =0 Ω In case of repetitive pulses, T_{jstart} (at beginning of each demagnetization) of every pulse must not exceed the temperature specified above for curves A and B.*

3.6 PPAK maximum demagnetization energy (V_{CC} = 13.5V)

Figure 27. PPAK maximum turn-off current versus inductance
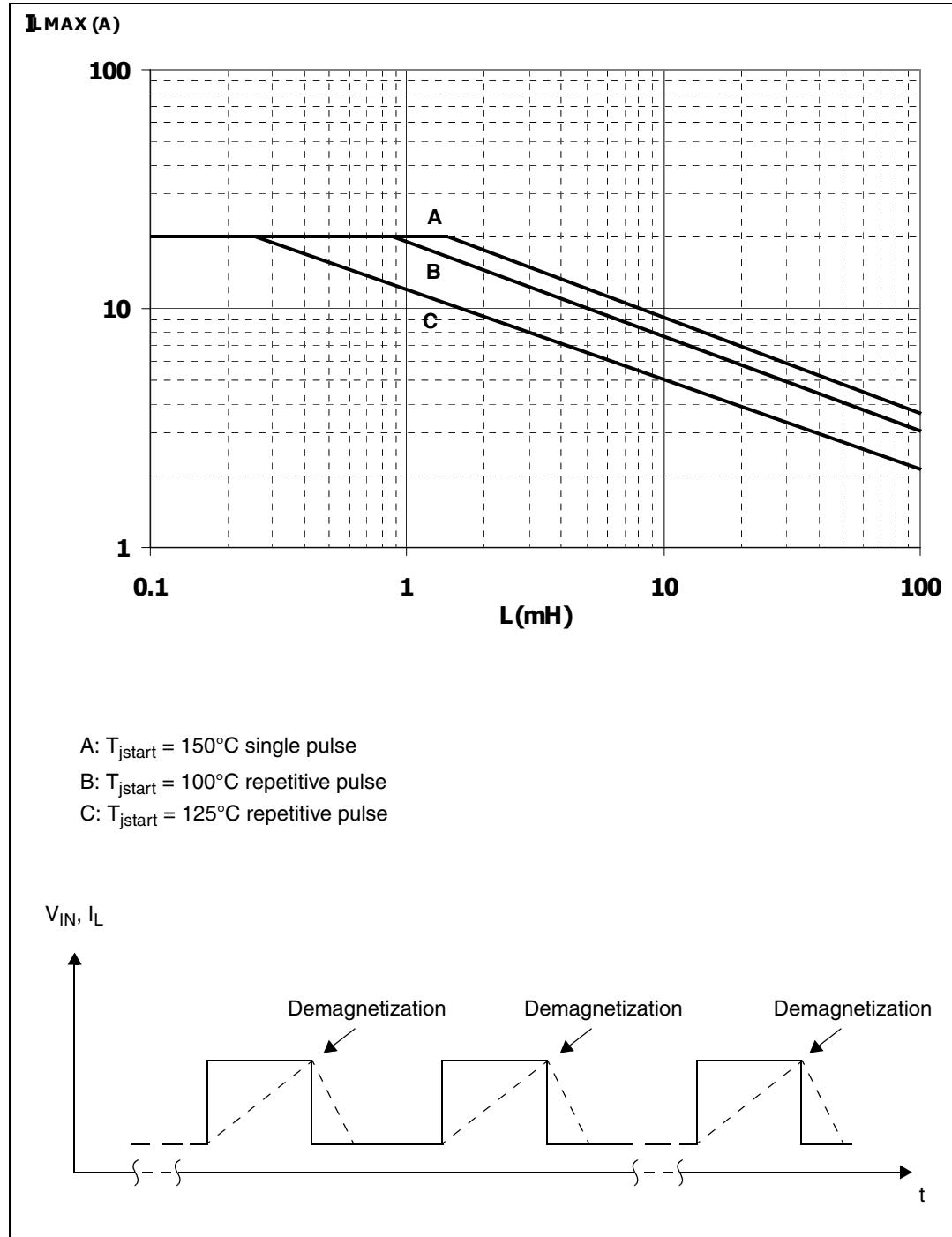
A: T_{jstart} = 150°C single pulse

B: T_{jstart} = 100°C repetitive pulse

C: T_{jstart} = 125°C repetitive pulse

Note: *Values are generated with R_L =0 Ω In case of repetitive pulses, T_{jstart} (at beginning of each demagnetization) of every pulse must not exceed the temperature specified above for curves A and B.*

3.7   SO-16L maximum demagnetization energy (V$_{CC}$ = 13.5V)

Figure 28.   SO-16L maximum turn-off current versus inductance

A: T$_{jstart}$ = 150°C single pulse

B: T$_{jstart}$ = 100°C repetitive pulse

C: T$_{jstart}$ = 125°C repetitive pulse

Note: *Values are generated with R$_L$ =0 Ω In case of repetitive pulses, T$_{jstart}$ (at beginning of each demagnetization) of every pulse must not exceed the temperature specified above for curves A and B.*

4 Package and PCB thermal data

4.1 SO-16L thermal data

Figure 29. SO-16L PC board
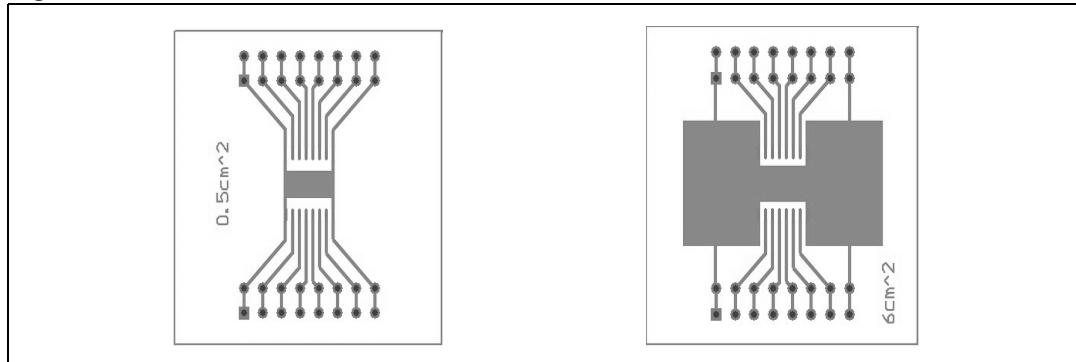
Note: *Layout condition of R_{th} and Z_{th} measurements (PCB FR4 area = 41mm x 48mm, PCB thickness = 2mm, Cu thickness = 35µm, Copper areas: 0.5cm^2, 6cm^2).*

Figure 30. $R_{thj-amb}$ Vs PCB copper area in open box free air condition
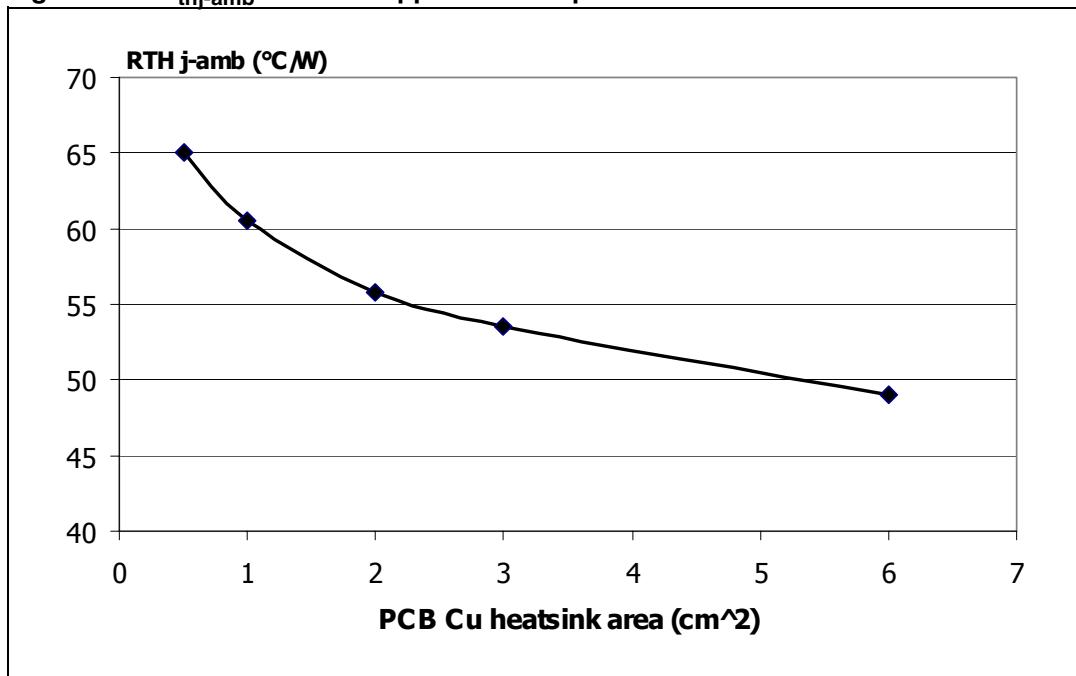
Figure 31.   Thermal impedance junction ambient single pulse
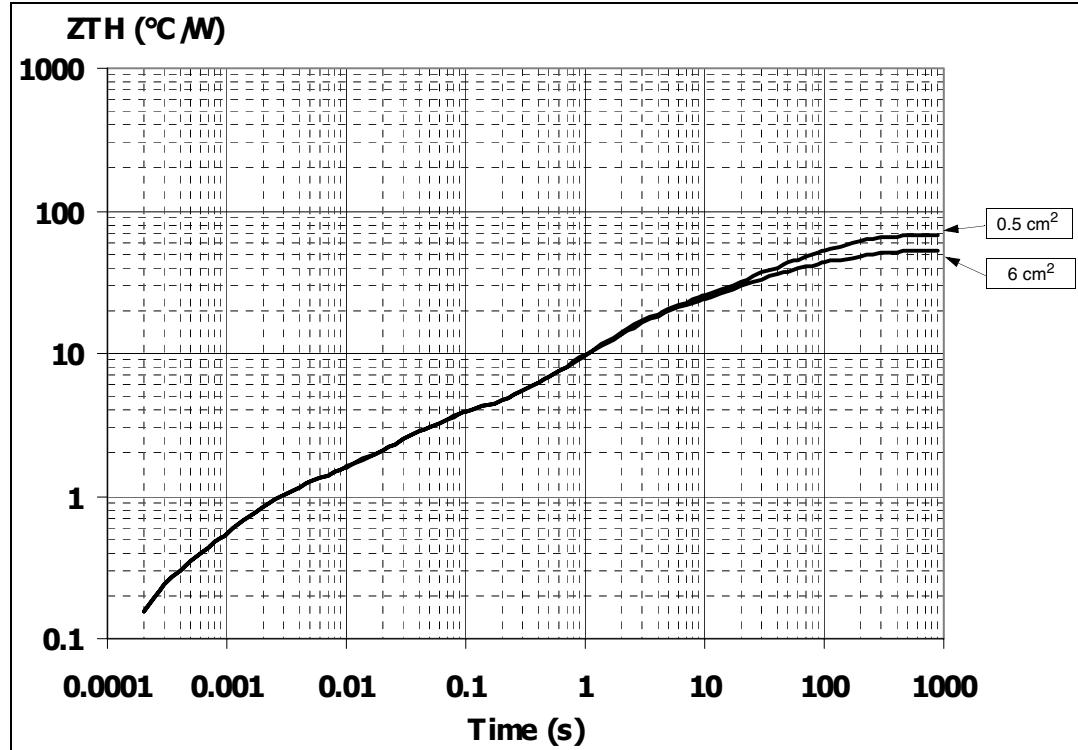
Equation 1: pulse calculation formula

$$Z_{TH\delta} = R_{TH} \cdot \delta + Z_{THtp}(1 - \delta)$$

where $\delta = t_p / T$

Figure 32.   Thermal fitting model of a single channel HSD in SO-16L
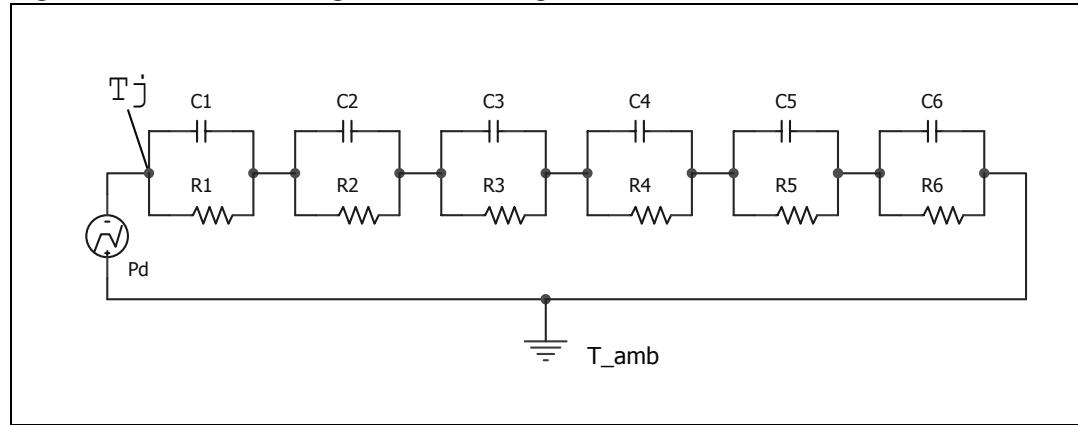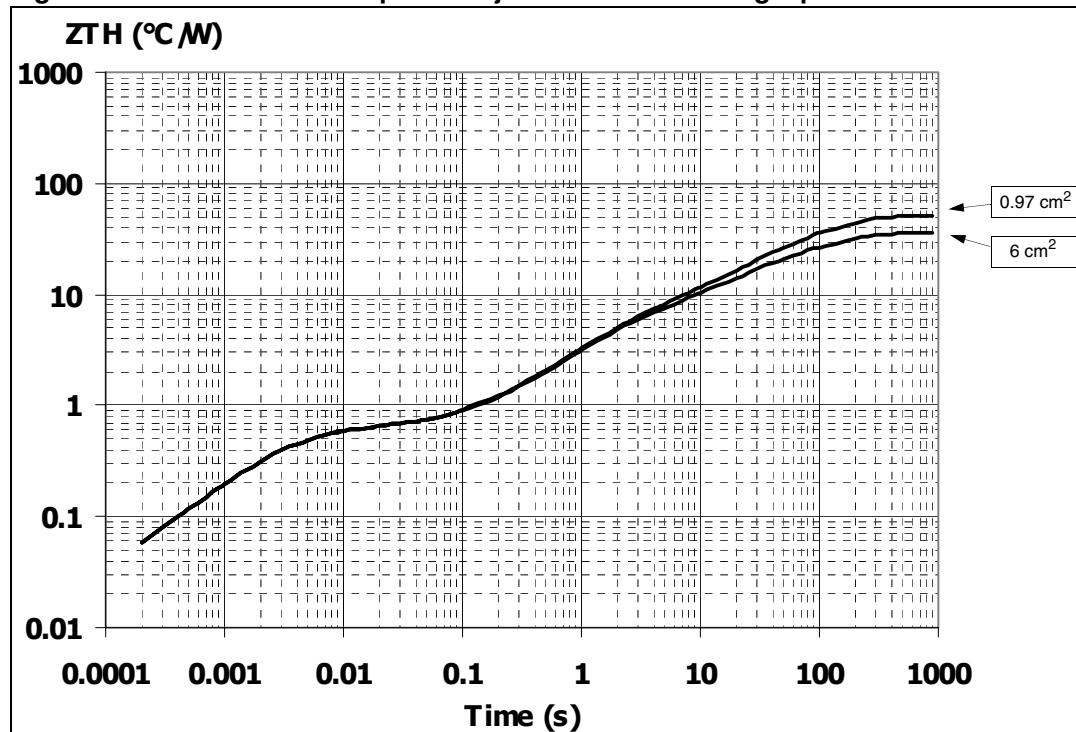
Table 14. **Thermal parameters**

Area / island (cm^2)	Footprint	6
R1 (°C/W)	0.04	
R2 (°C/W)	0.25	
R3 (°C/W)	2.2	
R4 (°C/W)	12	
R5 (°C/W)	15	
R6 (°C/W)	37	22
C1 (W.s/°C)	0.0008	
C2 (W.s/°C)	7E-03	
C3 (W.s/°C)	1.5E-02	
C4 (W.s/°C)	0.14	
C5 (W.s/°C)	1	
C6 (W.s/°C)	3	5

4.2 P^{2}PAK thermal data

Figure 33. **PC board**
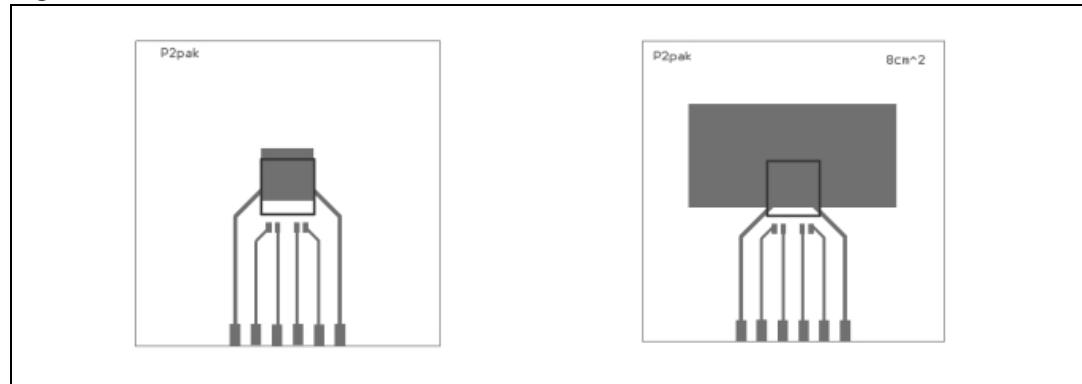
Note: *Layout condition of R_{th} and Z_{th} measurements (PCB FR4 area = 60mm x 60mm, PCB thickness = 2 mm, Cu thickness = 35μm , Copper areas: 0.97cm^2, 8cm^2).*

Figure 34. $R_{thj-amb}$ **Vs. PCB copper area in open box free air condition**
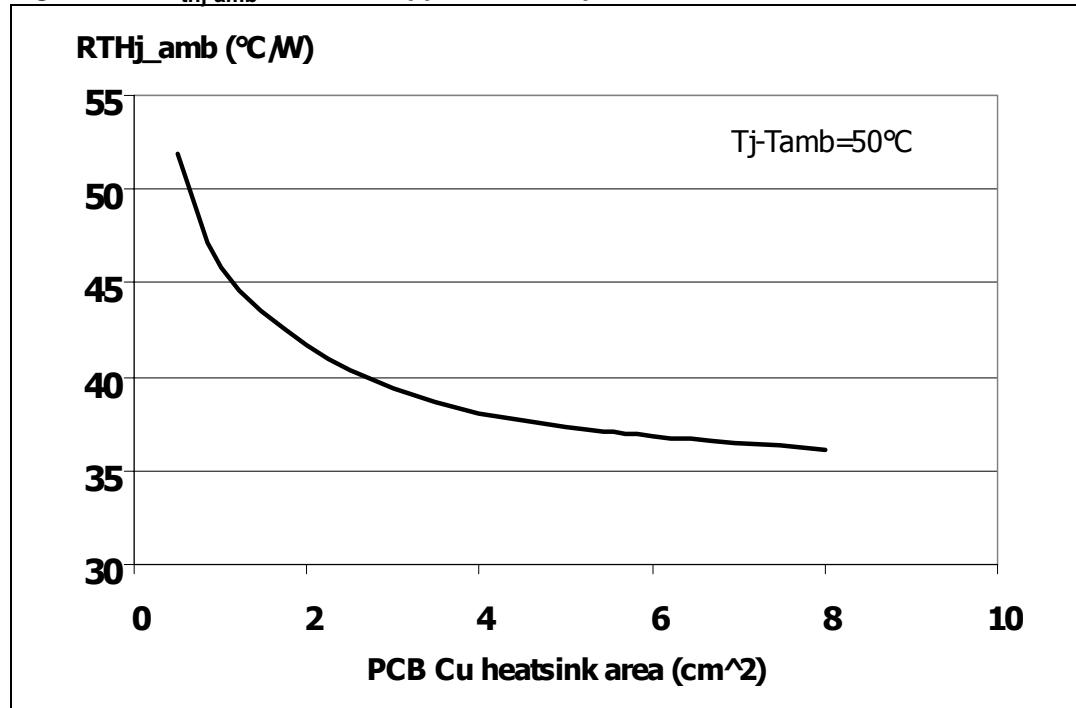
Figure 35. **P^{2}PAK thermal impedance junction ambient single pulse**

Equation 2: pulse calculation formula
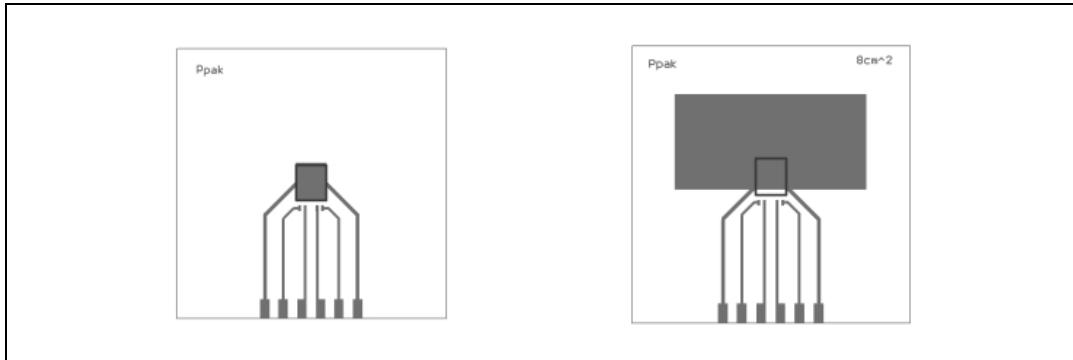
$$Z_{TH\delta} = R_{TH} \cdot \delta + Z_{THtp}(1-\delta)$$
where $\delta = t_P/T$

Figure 36.   Thermal fitting model of a single channel
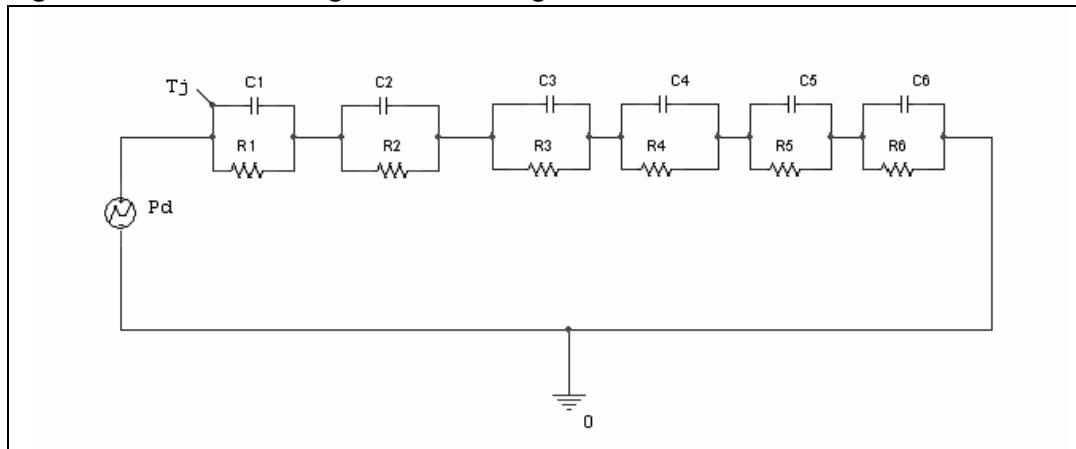
Table 15.   Thermal parameter

Area/island (cm^2)	0.97	6
R1 (°C/W)	0.04	
R2 (°C/W)	0.25	
R3 (°C/W)	0.3	
R4 (°C/W)	4	
R5 (°C/W)	9	
R6 (°C/W)	37	22
C1 (W·s/°C)	0.0008	
C2 (W·s/°C)	0.007	
C3 (W·s/°C)	0.015	
C4 (W·s/°C)	0.4	
C5 (W·s/°C)	2	
C6 (W·s/°C)	3	5

4.3 PPAK thermal data

Figure 37. PC board

Note: *Layout condition of R_{th} and Z_{th} measurements (PCB FR4 area = 60mm x 60mm, PCB thickness = 2 mm, Cu thickness=35μm , Copper areas: 0.44 cm^2, 8 cm^2).*

Figure 38. $R_{thj-amb}$ Vs. PCB copper area in open box free air condition
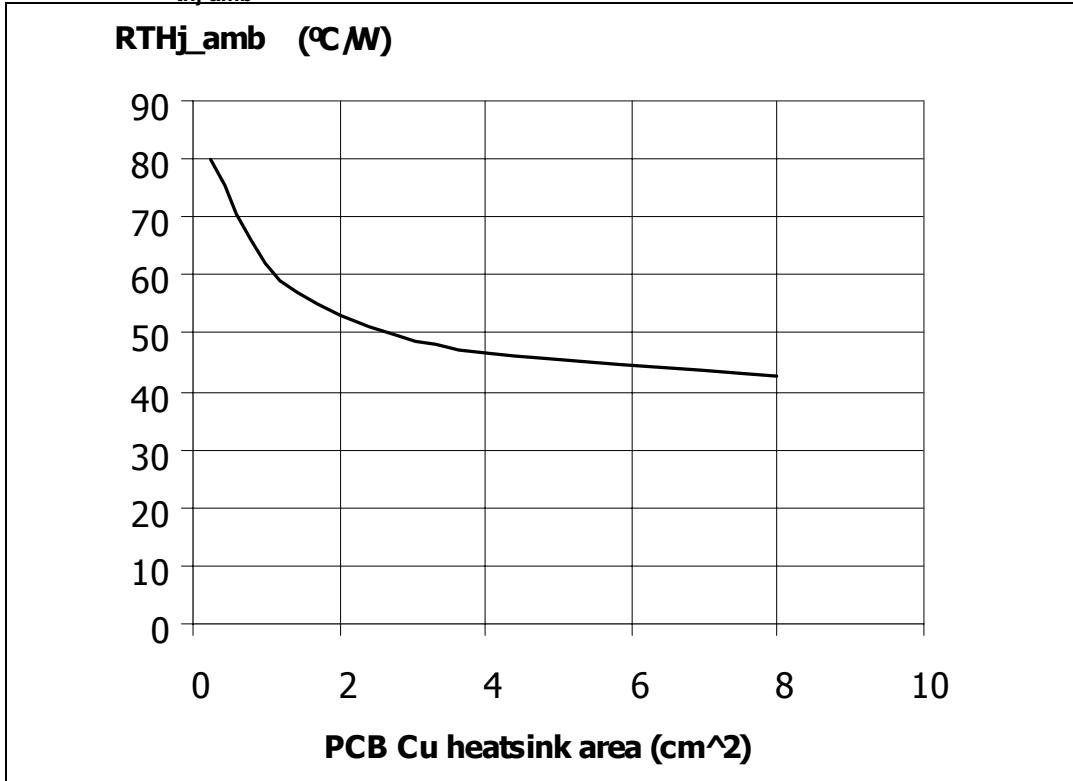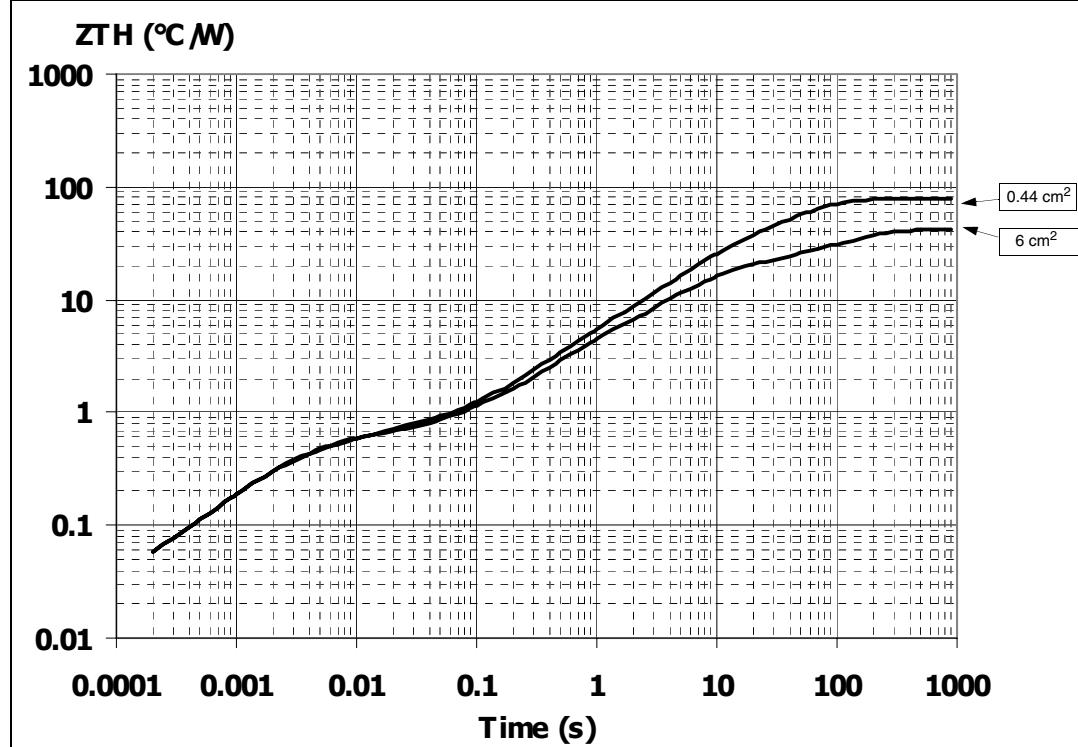
Figure 39. PPAK thermal impedance junction ambient single pulse

Equation 3: pulse calculation formula

$$Z_{TH\delta} = R_{TH} \cdot \delta + Z_{THtp}(1 - \delta)$$

where $\delta = t_P/T$

Figure 40. Thermal fitting model of a single channel
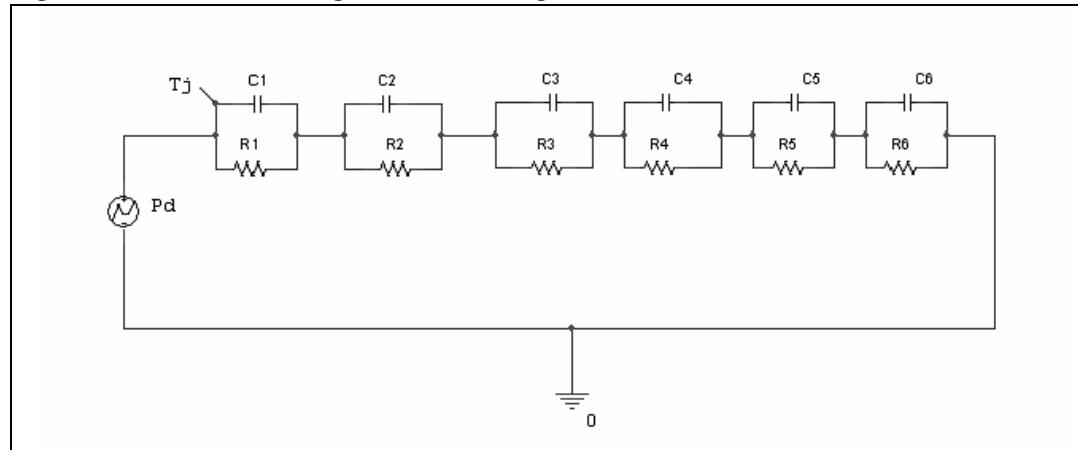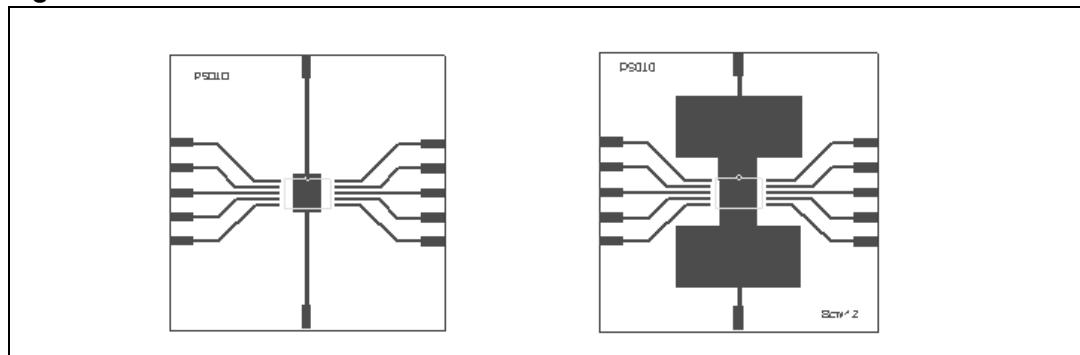
Table 16.   Thermal parameter

Area/island (cm^2)	0.44	6
R1 (°C/W)	0.04	
R2 (°C/W)	0.25	
R3 (°C/W)	0.3	
R4 (°C/W)	2	
R5 (°C/W)	15	
R6 (°C/W)	61	24
C1 (W·s/°C)	0.0008	
C2 (W·s/°C)	0.007	
C3 (W·s/°C)	0.02	
C4 (W·s/°C)	0.3	
C5 (W·s/°C)	0.45	
C6 (W·s/°C)	0.8	5

4.4   PowerSO-10 thermal data

Figure 41.   PowerSO-10 PC board

Note: *Layout condition of R_{th} and Z_{th} measurements (PCB FR4 area = 58mm x 58mm, PCB thickness = 2mm, Cu thickness = 35µm, Copper areas: from minimum pad lay-out to 8cm^2).*
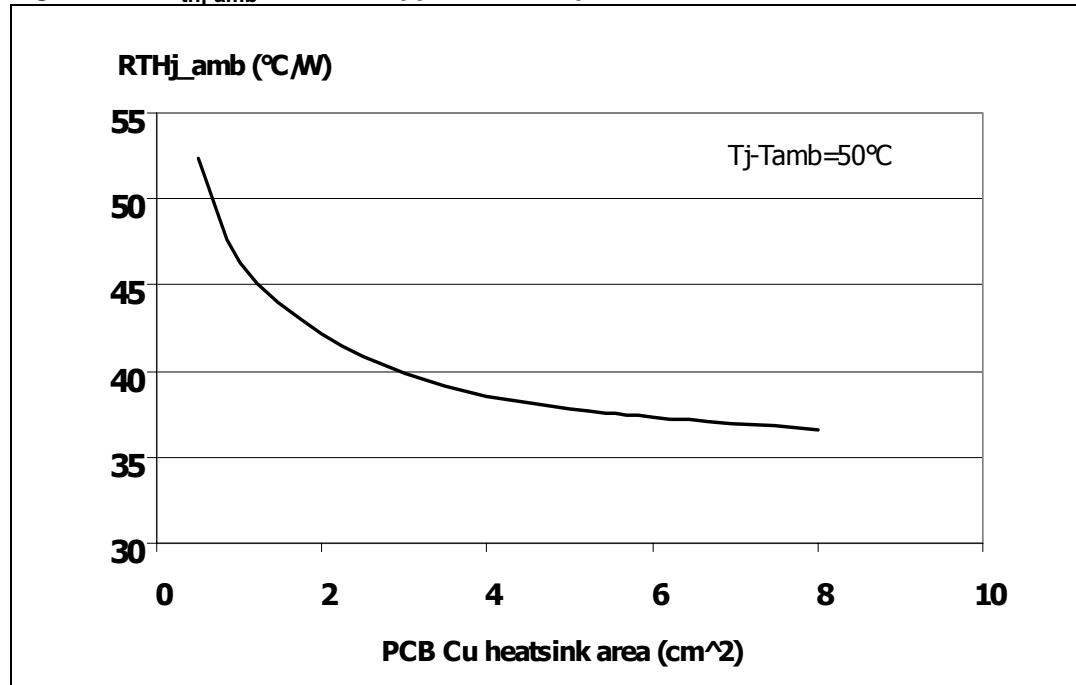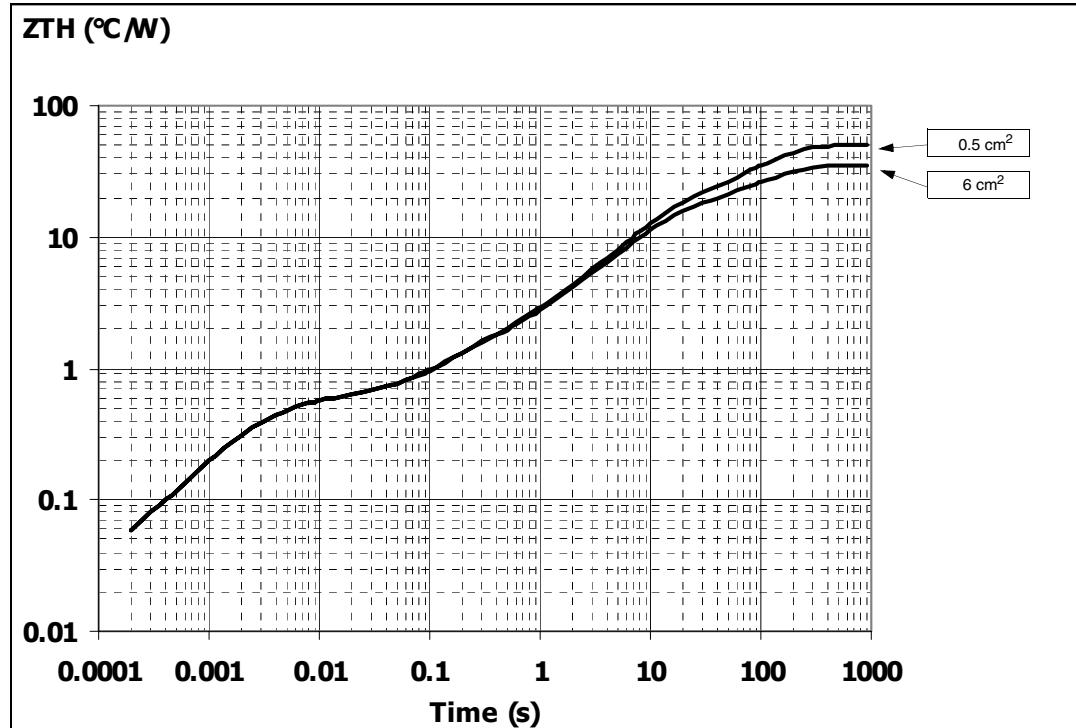
Figure 42. R$_{thj\text{-}amb}$ **Vs PCB copper area in open box free air condition**


Figure 43. **Thermal impedance junction ambient single pulse**

Equation 4: pulse calculation formula

$$Z_{TH\delta} = R_{TH} \cdot \delta + Z_{THtp}(1 - \delta)$$
$$\text{where} \quad \delta = t_p / T$$

**Figure 44. Thermal fitting model of a single channel HSD in PowerSO-10**
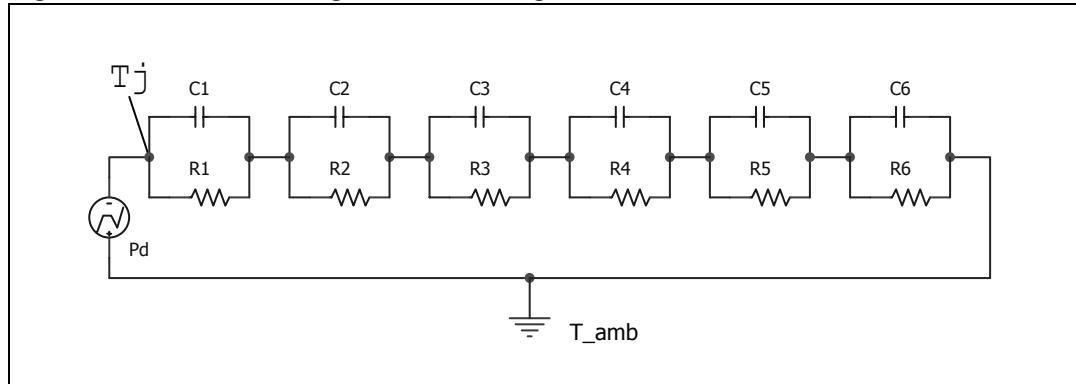
Table 17. Thermal parameters

Area / island (cm^2)	Footprint	6
R1 (°C/W)	0.04	
R2 (°C/W)	0.25	
R3 (°C/W)	0.25	
R4 (°C/W)	0.8	
R5 (°C/W)	12	
R6 (°C/W)	37	22
C1 (W.s/°C)	0.0008	
C2 (W.s/°C)	7E-03	
C3 (W.s/°C)	0.015	
C4 (W.s/°C)	0.3	
C5 (W.s/°C)	0.75	
C6 (W.s/°C)	3	5

5 Package and packing information

5.1 ECOPACK® packages

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

Figure 45. SO-16L package dimensions
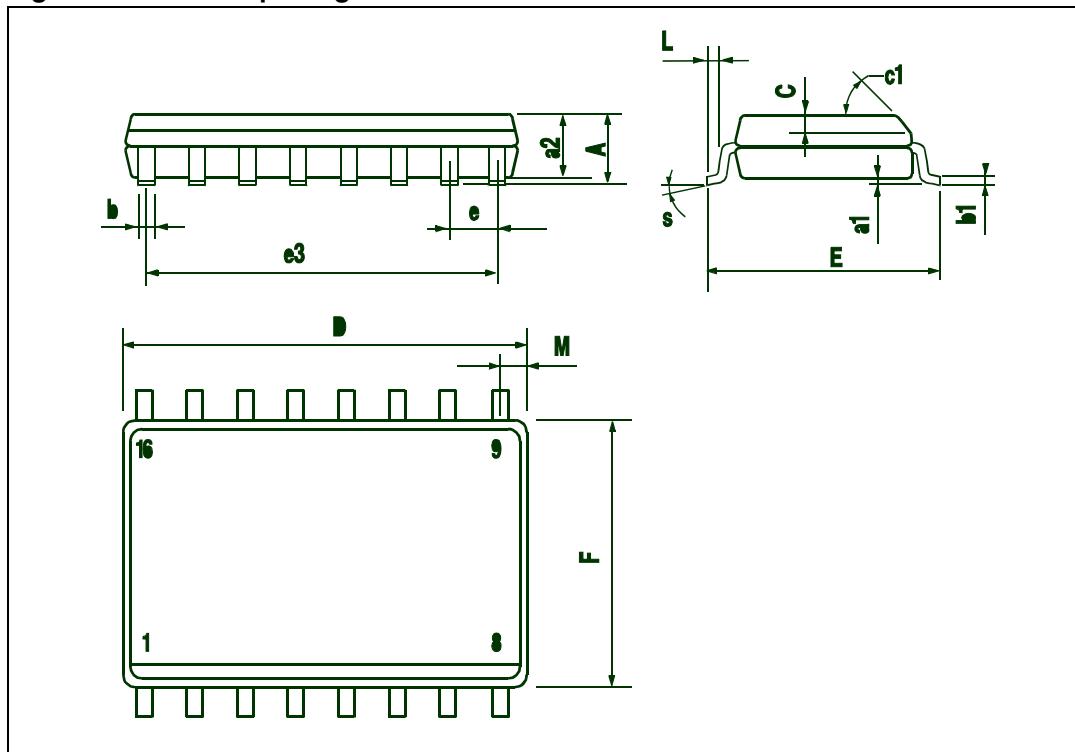
Table 18. SO-16L mechanical data

DIM.	mm.		
	Min.	**Typ.**	**Max.**
A			2.65
a1	0.1		0.2
a2			2.45
b	0.35		0.49
b1	0.23		0.32
C		0.5	
c1	45° (typ.)		

Table 18.   SO-16L mechanical data (continued)

DIM.	mm.		
	Min.	Typ.	Max.
D	10.1		10.5
E	10.0		10.65
e		1.27	
e3		8.89	
F	7.4		7.6
L	0.5		1.27
M			0.75
S		8° (max.)	

5.2   PENTAWATT mechanical data

Figure 46.   PENTAWATT package dimensions
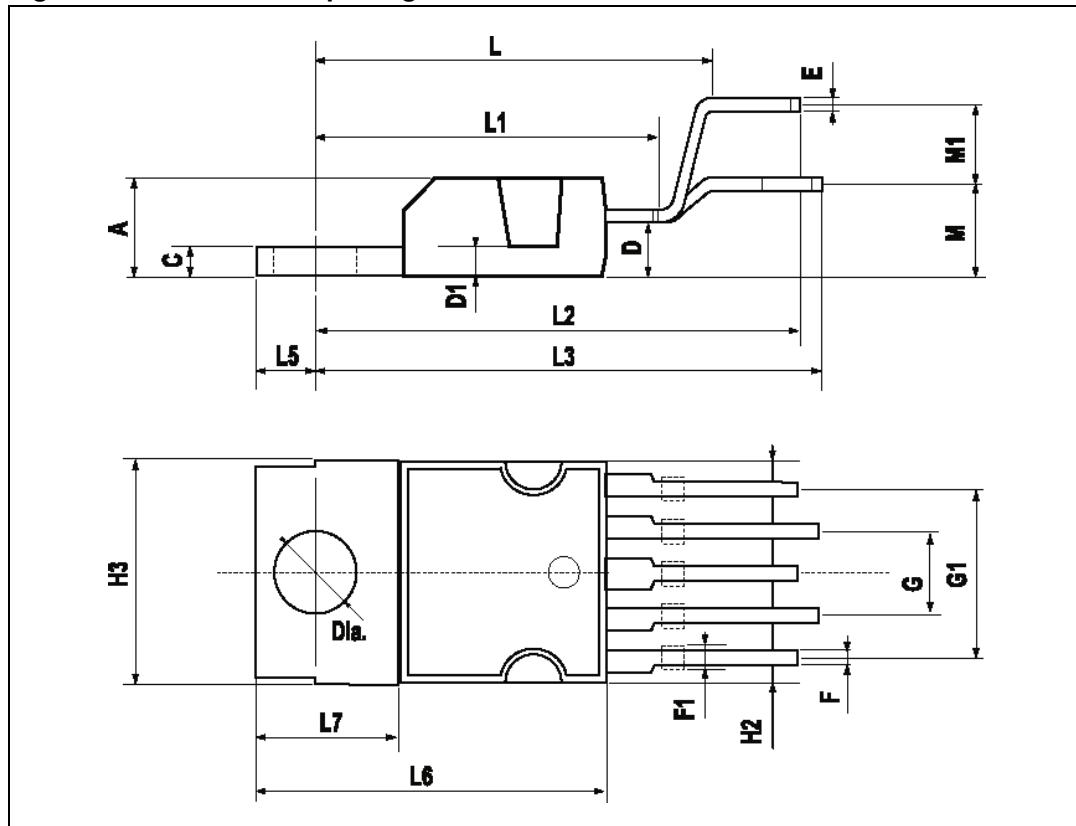
Table 19.   PENTAWATT mechanical data

Dim.	mm		
	Min.	**Typ.**	**Max.**
A			4.8
C			1.37
D	2.4		2.8
D1	1.2		1.35
E	0.35		0.55
F	0.8		1.05
F1	1		1.4
G	3.2	3.4	3.6
G1	6.6	6.8	7
H2			10.4
H3	10.05		10.4
L		17.85	
L1		15.75	
L2		21.4	
L3		22.5	
L5	2.6		3
L6	15.1		15.8
L7	6		6.6
M		4.5	
M1		4	
Diam.	3.65		3.85

5.3   P²PAK mechanical data

Figure 47.   P²PAK package dimensions

TERMINAL LENGTH FOR SOLDERING NO LESS THAN 1 mm
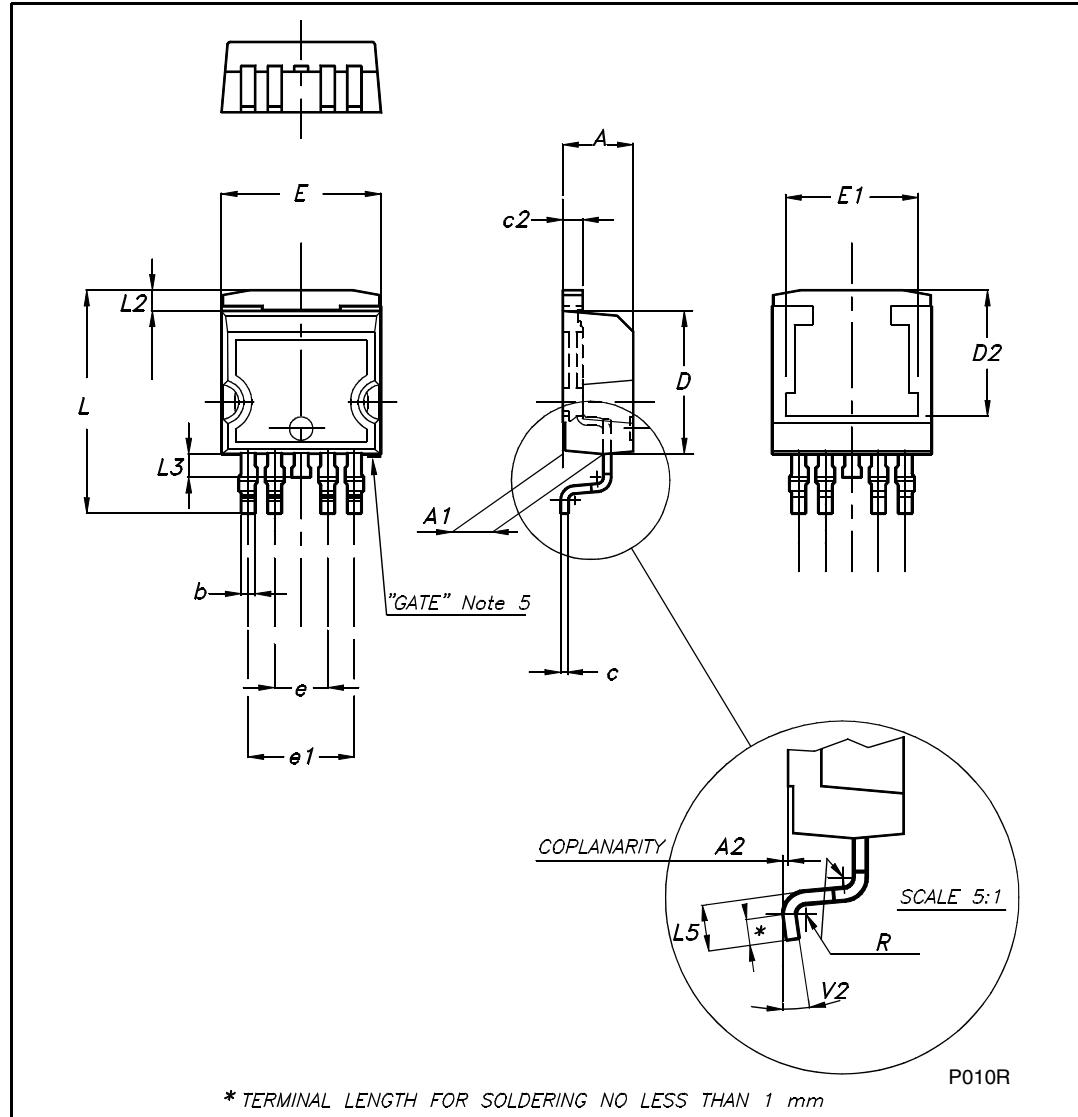
Table 20.   P²PAK mechanical data

Dim.	mm		
	Min.	**Typ.**	**Max.**
A	4.30		4.80
A1	2.40		2.80
A2	0.03		0.23
b	0.80		1.05
c	0.45		0.60
c2	1.17		1.37
D	8.95		9.35
D2		8.00	
E	10.00		10.40
E1		8.50	
e	3.20		3.60
e1	6.60		7.00
L	13.70		14.50
L2	1.25		1.40
L3	0.90		1.70
L5	1.55		2.40
R		0.40	
V2	0º		8º
Package weight	1.40 Gr (typ)		

5.4 PPAK mechanical data

Figure 48. PPAK package dimensions
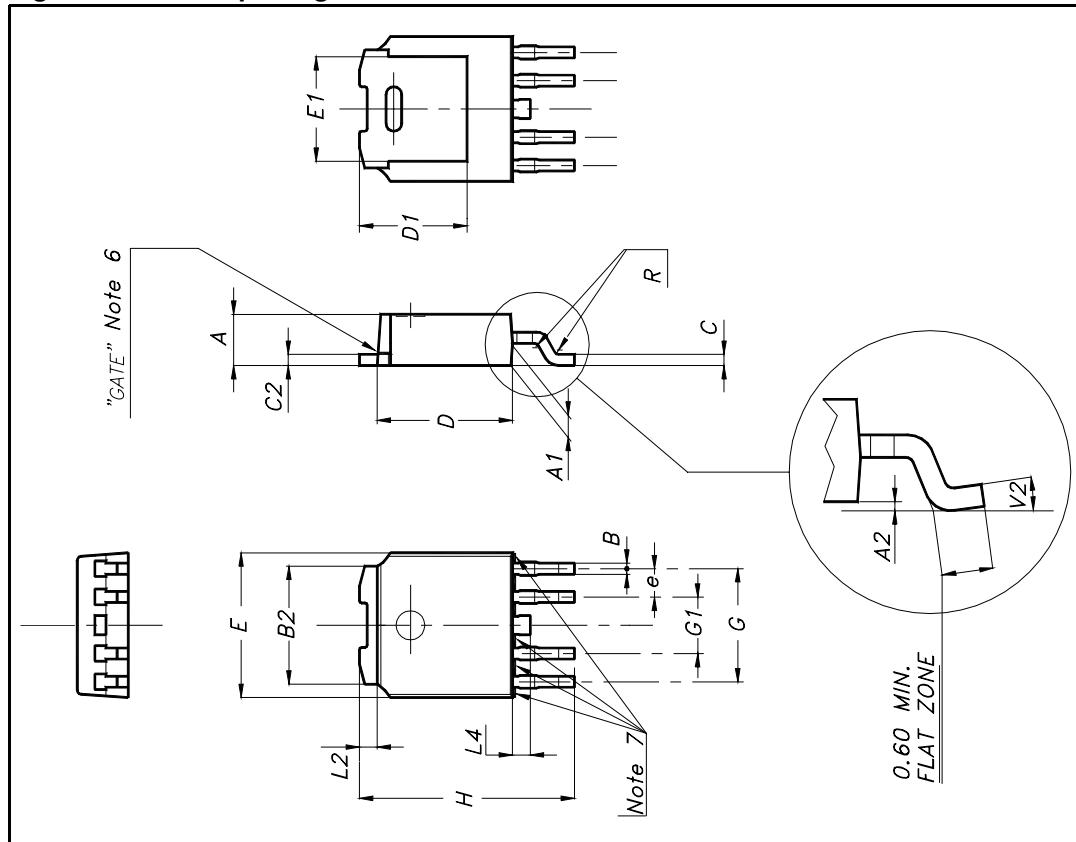
Table 21. PPAK mechanical data

Dim.	mm		
	Min.	**Typ.**	**Max.**
A	2.20		2.40
A1	0.90		1.10
A2	0.03		0.23
B	0.40		0.60
B2	5.20		5.40
C	0.45		0.60
C2	0.48		0.60
D1		5.1	
D	6.00		6.20
E	6.40		6.60

Table 21.   PPAK mechanical data (continued)

Dim.	mm		
	Min.	**Typ.**	**Max.**
E1		4.7	
e		1.27	
G	4.90		5.25
G1	2.38		2.70
H	9.35		10.10
L2		0.8	1.00
L4	0.60		1.00
R		0.2	
V2	0º		8º
Package weight	Gr. 0.3		

5.5   PowerSO-10 mechanical data
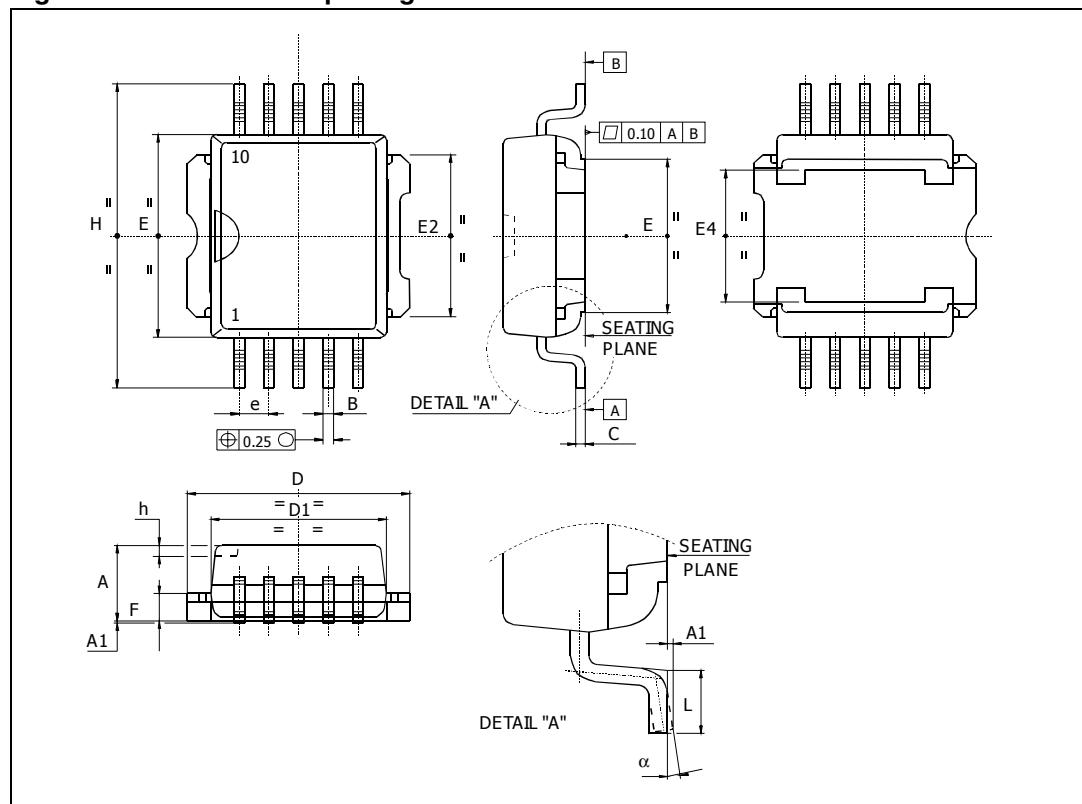
Figure 49.   PowerSO-10 package dimensions

Table 22.   PowerSO-10 mechanical data

Dim.	mm		
	Min.	**Typ.**	**Max.**
A	3.35		3.65
A[1]	3.4		3.6
A1	0		0.10
B	0.40		0.60
B[1]	0.37		0.53
C	0.35		0.55
C[1]	0.23		0.32
D	9.40		9.60
D1	7.40		7.60
E	9.30		9.50
E2	7.20		7.60
E2[1]	7.30		7.50
E4	5.90		6.10
E4[1]	5.90		6.30
e		1.27	
F	1.25		1.35
F[1]	1.20		1.40
H	13.80		14.40
H[1]	13.85		14.35
h		0.50	
L	1.20		1.80
L[1]	0.80		1.10
α	0°		8°
α[1]	2°		8°

1.   Muar only POA P013P.

5.6 SO-16L packing information

Figure 50. SO-16L tube shipment (no suffix)

Base Q.ty	50
Bulk Q.ty	1000
Tube length (± 0.5)	532
A	3.5
B	13.8
C (± 0.1)	0.6

All dimensions are in mm.
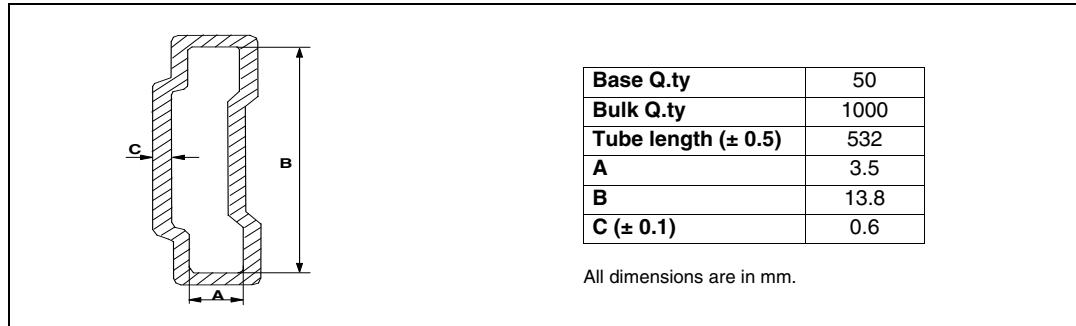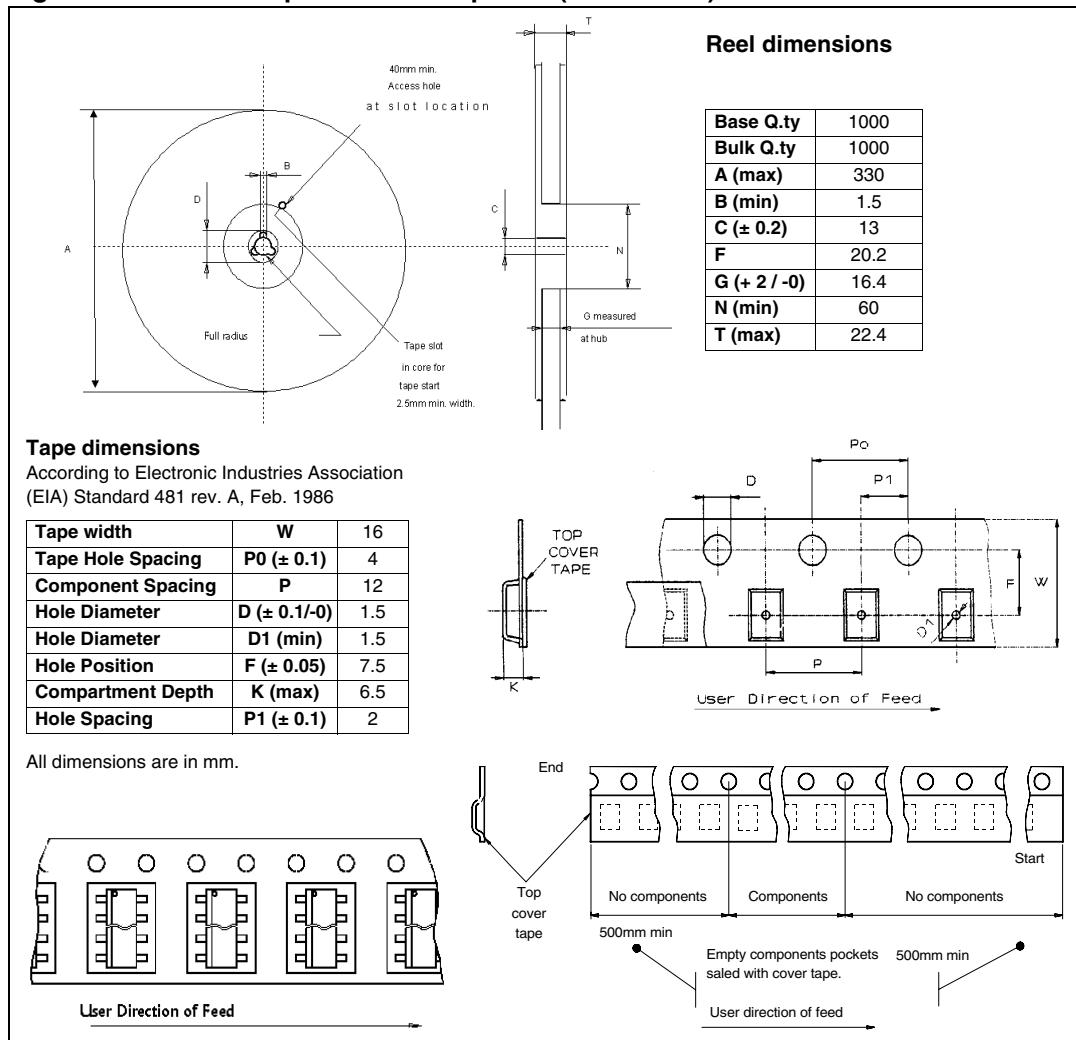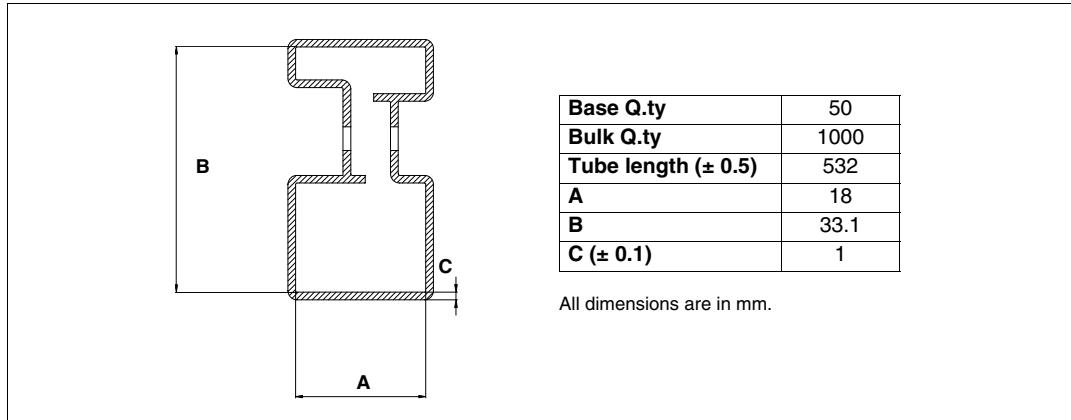
Figure 51. SO-16L tape and reel shipment (suffix "TR")

Reel dimensions

Base Q.ty	1000
Bulk Q.ty	1000
A (max)	330
B (min)	1.5
C (± 0.2)	13
F	20.2
G (+ 2 / -0)	16.4
N (min)	60
T (max)	22.4

Tape dimensions

According to Electronic Industries Association
(EIA) Standard 481 rev. A, Feb. 1986

Tape width	W	16
Tape Hole Spacing	P0 (± 0.1)	4
Component Spacing	P	12
Hole Diameter	D (± 0.1/-0)	1.5
Hole Diameter	D1 (min)	1.5
Hole Position	F (± 0.05)	7.5
Compartment Depth	K (max)	6.5
Hole Spacing	P1 (± 0.1)	2

All dimensions are in mm.

5.7   PENTAWATT packing information

Figure 52.   PENTAWATT tube shipment (no suffix)

Base Q.ty	50
Bulk Q.ty	1000
Tube length (± 0.5)	532
A	18
B	33.1
C (± 0.1)	1

All dimensions are in mm.

5.8   P^{2}PAK packing information

Figure 53.   P^{2}PAK tube shipment (no suffix)

Base Q.ty	50
Bulk Q.ty	1000
Tube length (± 0.5)	532
A	18
B	33.1
C (± 0.1)	1

All dimensions are in mm.

Figure 54.   P²PAK tape and reel (suffix "13TR")

REEL DIMENSIONS

All dimensions are in mm.

Base Q.ty	1000
Bulk Q.ty	1000
A (max)	330
B (min)	1.5
C (± 0.2)	13
F	20.2
G (+ 2 / -0)	24.4
N (min)	60
T (max)	30.4

TAPE DIMENSIONS

According to Electronic Industries Association
(EIA) Standard 481 rev. A, Feb 1986

Tape width	**W**	24
Tape Hole Spacing	**P0 (± 0.1)**	4
Component Spacing	**P**	12
Hole Diameter	**D (± 0.1/-0)**	1.5
Hole Diameter	**D1 (min)**	1.5
Hole Position	**F (± 0.05)**	11.5
Compartment Depth	**K (max)**	6.5
Hole Spacing	**P1 (± 0.1)**	2

All dimensions are in mm.

5.9   PPAK packing information

Figure 55.   PPAK suggested pad layout
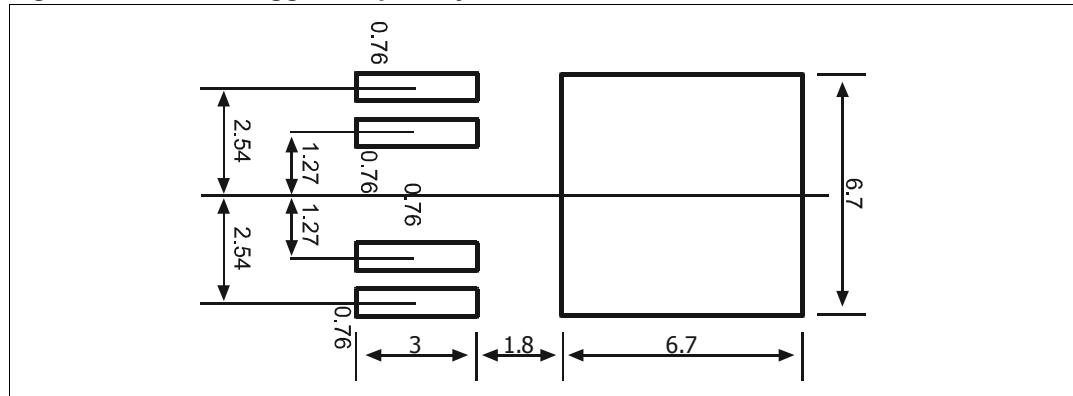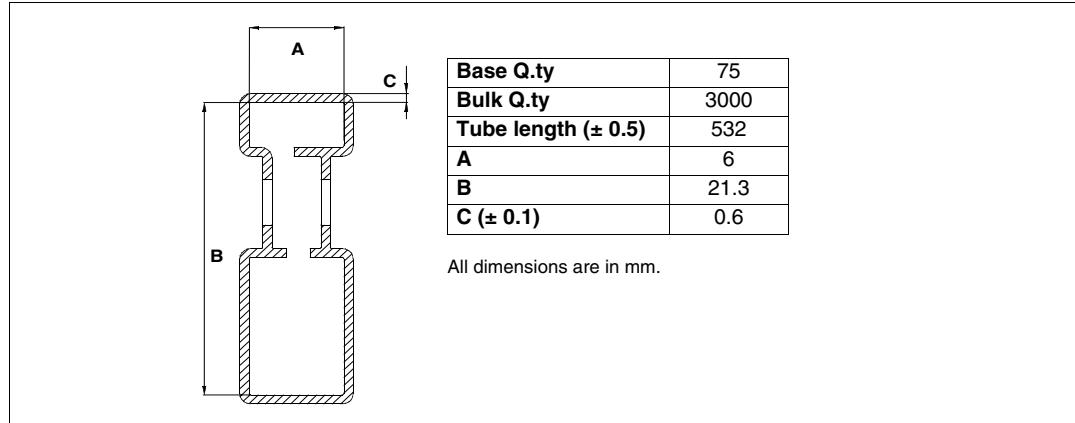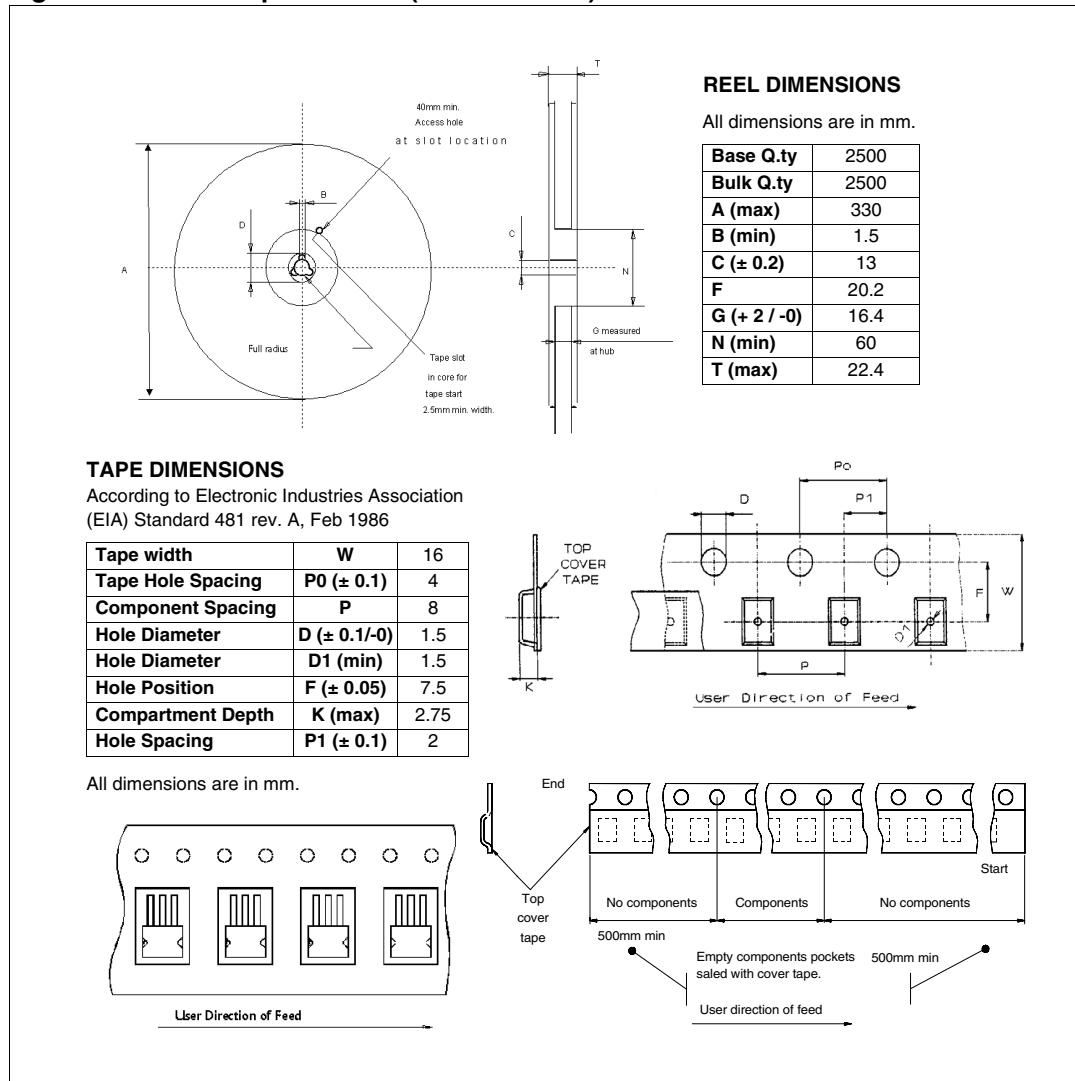
Figure 56.   PPAK tube shipment (no suffix)

Base Q.ty	75
Bulk Q.ty	3000
Tube length (± 0.5)	532
A	6
B	21.3
C (± 0.1)	0.6

All dimensions are in mm.

Figure 57.   PPAK tape and reel (suffix "13TR")

REEL DIMENSIONS

All dimensions are in mm.

Base Q.ty	2500
Bulk Q.ty	2500
A (max)	330
B (min)	1.5
C (± 0.2)	13
F	20.2
G (+ 2 / -0)	16.4
N (min)	60
T (max)	22.4

TAPE DIMENSIONS

According to Electronic Industries Association (EIA) Standard 481 rev. A, Feb 1986

Tape width	W	16
Tape Hole Spacing	P0 (± 0.1)	4
Component Spacing	P	8
Hole Diameter	D (± 0.1/-0)	1.5
Hole Diameter	D1 (min)	1.5
Hole Position	F (± 0.05)	7.5
Compartment Depth	K (max)	2.75
Hole Spacing	P1 (± 0.1)	2

All dimensions are in mm.

5.10 PowerSO-10 packing information

Figure 58. PowerSO-10 suggested pad layout
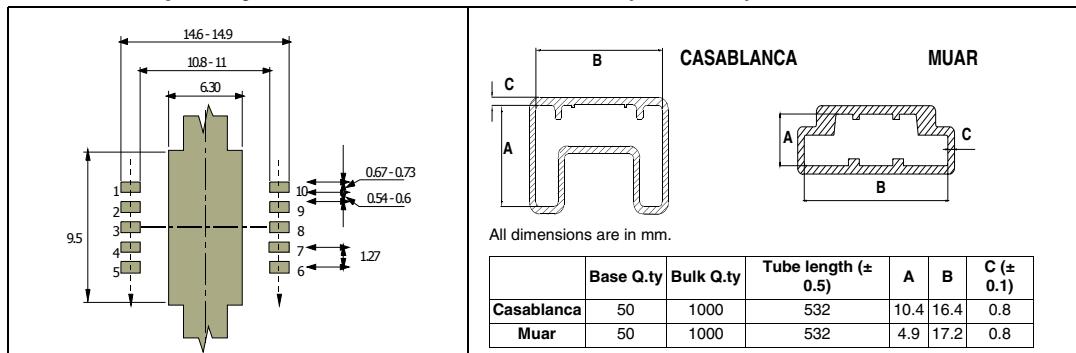
Figure 59. PowerSO-10 tube shipment (no suffix)

All dimensions are in mm.

	Base Q.ty	Bulk Q.ty	Tube length (± 0.5)	A	B	C (± 0.1)
Casablanca	50	1000	532	10.4	16.4	0.8
Muar	50	1000	532	4.9	17.2	0.8
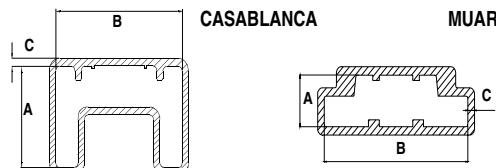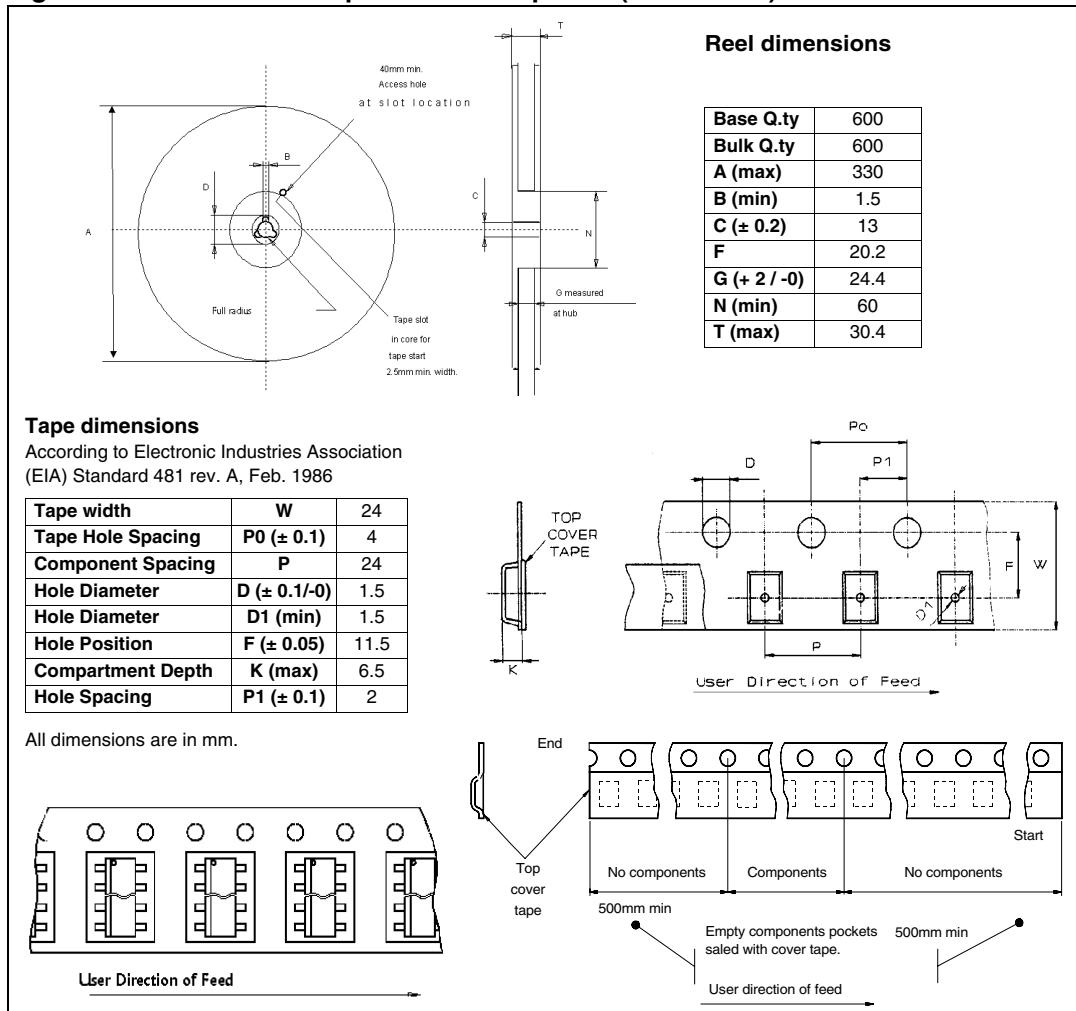
Figure 60. PowerSO-10 tape and reel shipment (suffix "TR")

Reel dimensions

Base Q.ty	600
Bulk Q.ty	600
A (max)	330
B (min)	1.5
C (± 0.2)	13
F	20.2
G (+ 2 / -0)	24.4
N (min)	60
T (max)	30.4

Tape dimensions

According to Electronic Industries Association (EIA) Standard 481 rev. A, Feb. 1986

Tape width	W	24
Tape Hole Spacing	P0 (± 0.1)	4
Component Spacing	P	24
Hole Diameter	D (± 0.1/-0)	1.5
Hole Diameter	D1 (min)	1.5
Hole Position	F (± 0.05)	11.5
Compartment Depth	K (max)	6.5
Hole Spacing	P1 (± 0.1)	2

All dimensions are in mm.

6   Revision history

Table 23.   Document revision history

Date	Revision	Changes
07-Jul-2004	1	Initial release.
03-May-2006	2	Minor changes Current and voltage convention update (page 2). Configuration diagram (top view) and suggested connections for unused and n.c. pins insertion (page 2). 6 cm2 Cu condition insertion in thermal data table (page 3). V_{CC} - output diode section update (page 4). Revision history table insertion (page 34). Disclaimers update (page 35).
17-Dec-2008	3	Document reformatted and restructured. Added content, list of figures and tables. Added *ECOPACK® packages* information. Updated *Figure 54.: P²PAK tape and reel (suffix "13TR")*: – changed component spacing (P) in tape dimensions table from 16 mm to 12 mm.

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